# **TJA1145A**

High-speed CAN transceiver for partial networking

Rev. 2 — 23 September 2020

**Product data sheet** 

# 1. General description

The TJA1145A is a high-speed CAN transceiver that provides an interface between a Controller Area Network (CAN) protocol controller and the physical two-wire CAN bus. The transceiver is designed for high-speed CAN applications in the automotive industry, providing differential transmit and receive capability to (a microcontroller with) a CAN protocol controller.

The TJA1145A features very low power consumption in Standby and Sleep modes and supports ISO 11898-2:2016 compliant CAN Partial Networking by means of a selective wake-up function.

A dedicated implementation of the partial networking function has been embedded into the FD variants TJA1145AT/FD and TJA1145ATK/FD (see <u>Section 7.3.2</u> for further details on CAN FD). This function is called 'FD-passive' and is the ability to ignore CAN FD frames while waiting for a valid wake-up frame in Sleep/Standby mode. This additional feature of partial networking is the perfect fit for networks that support both CAN FD and standard CAN 2.0 communications. It allows normal CAN controllers that do not need to communicate CAN FD messages to remain in partial networking Sleep/Standby mode during CAN FD communication without generating bus errors.

Advanced power management regulates the supply throughout the node and supports local and remote wake-up functionality. I/O levels are automatically adjusted to the I/O levels of the controller, allowing the TJA1145A to interface directly with 3.3 V to 5 V microcontrollers. An SPI interface is provided for transceiver control and for retrieving status information. Bus connections are truly floating when power is off.

The TJA1145A implements the CAN physical layer as defined in ISO 11898-2:2016 and SAE J2284-1 to SAE J2284-5. This implementation enables reliable communication in the CAN FD fast phase at data rates up to 5 Mbit/s.

These features make the TJA1145A the ideal choice for high-speed CAN networks containing nodes that are always connected to the battery supply line but, in order to minimize current consumption, are only active when required by the application.

# 2. Features and benefits

### 2.1 General

- ISO 11898-2:2016 and SAE J2284-1 to SAE J2284-5 compliant
- Timing guaranteed for data rates up to 5 Mbit/s in the CAN FD fast phase
- Autonomous bus biasing
- Optimized for in-vehicle high-speed CAN communication
- No 'false' wake-ups due to CAN FD in TJA1145Ax/FD variants



Hardware and software compatible with the TJA1145, with improved EMC performance

### 2.2 Designed for automotive applications

- ±8 kV ElectroStatic Discharge (ESD) protection, according to the Human Body Model (HBM) on the CAN bus pins
- ±6 kV ESD protection, according to IEC TS 62228 on pins BAT and WAKE and on the CAN bus pins
- CAN bus pins short-circuit proof to ±58 V
- Battery and CAN bus pins protected against transients according to ISO 7637-3, test pulses 1, 2a, 3a and 3b.
- Suitable for use in 12 V and 24 V systems
- Available in SO14 and leadless HVSON14 package (3 mm × 4.5 mm) with improved Automated Optical Inspection (AOI) capability
- AEC-Q100 qualified
- Dark green product (halogen free and Restriction of Hazardous Substances (RoHS) compliant)

### 2.3 Advanced ECU power management system

- Very low-current Standby and Sleep modes, with full wake-up capability
- Entire node can be powered down via the inhibit output
- Remote wake-up capability via standard CAN wake-up pattern or via ISO 11898-2:2016 compliant selective wake-up frame detection
- Local wake-up via the WAKE pin
- Wake-up source recognition
- Bit rates of 50 kbit/s, 100 kbit/s, 125 kbit/s, 250 kbit/s, 500 kbit/s and 1 Mbit/s supported during selective wake-up'
- Local wake-up can be disabled to reduce current consumption
- Transceiver disengages from the bus when the battery supply is removed
- VIO input allows for direct interfacing with 3.3 V to 5 V microcontrollers

### 2.4 Protection and diagnosis

- 16-, 24- or 32-bit SPI for configuration, control and diagnosis
- Transmit Data (TXD) dominant time-out function with diagnosis
- Overtemperature warning and shut-down
- Undervoltage detection and recovery on pins VCC, VIO and BAT
- Cold start diagnosis (via bits PO and NMS)
- Advanced system and transceiver interrupt handling

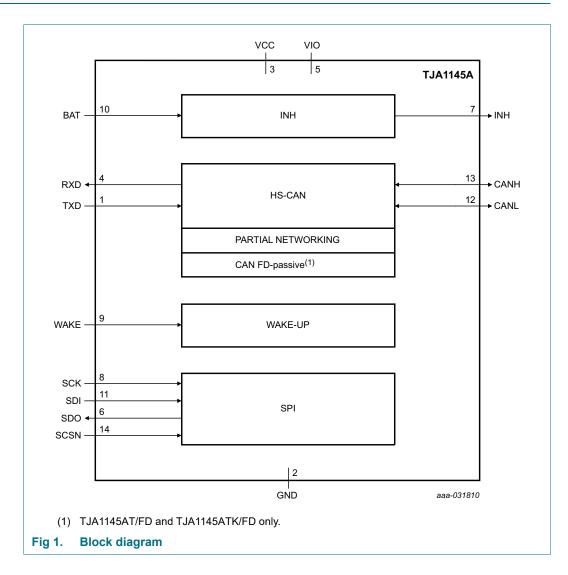
# 3. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>BAT</sub>	battery supply voltage		4.5	-	28	V
V <sub>CC</sub>	supply voltage		4.5	-	5.5	V
V <sub>IO</sub>	supply voltage on pin V <sub>IO</sub>		2.85	-	5.5	V
V <sub>th(det)poff</sub>	power-off detection threshold voltage	V <sub>BAT</sub> falling	2.8	-	3	V
V <sub>uvd(VCC)</sub>	undervoltage detection voltage on pin VCC		4.5	-	4.75	V
V <sub>uvd(VIO)</sub>	undervoltage detection voltage on pin VIO	V <sub>BAT</sub> > 4.5 V		-	2.85	V
ват	battery supply current	Normal mode	-	1	1.5	mA
		Sleep mode; CAN Offline mode; –40 °C < T <sub>vj</sub> < 85 °C; V <sub>BAT</sub> = 7 V to 18 V	-	48	64	μA
		Standby mode; CAN Offline mode; –40 °C < T <sub>vj</sub> < 85 °C; V <sub>BAT</sub> = 7 V to 18 V	-	56	73	μA
l <sub>cc</sub>	supply current	CAN Active mode; CAN recessive; $V_{TXD} = V_{IO}$	-	3	6	mA
		CAN Active mode; CAN dominant; V <sub>TXD</sub> = 0 V	-	45	65	mA
		Standby/Normal mode; CAN inactive; –40 °C < T <sub>vj</sub> < 85 °C	-	4.7	8.5	μA
		Sleep mode; CAN inactive; –40 °C < T <sub>vj</sub> < 85 °C	-	3.8	7	μA
ю	supply current on pin V <sub>IO</sub>	Standby/Normal mode; –40 °C < T <sub>vj</sub> < 85 °C	-	7.1	11	μA
		Sleep mode; –40 °C < T <sub>vj</sub> < 85 °C	-	5	8	μA
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2 on pins CANH, CANL	-6	-	+6	kV
V <sub>CANH</sub>	voltage on pin CANH		-58	-	+58	V
VCANL	voltage on pin CANL		-58	-	+58	V
T <sub>vi</sub>	virtual junction temperature		-40	-	+150	°C

# 4. Ordering information

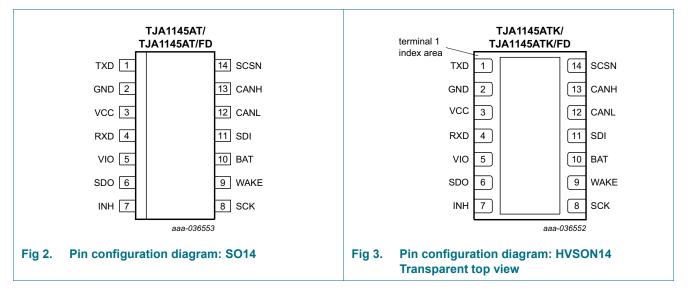
Type number	Package								
	Name Description								
TJA1145AT	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1						
TJA1145AT/FD	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1						
TJA1145ATK	HVSON14	plastic thermal enhanced very thin small outline package; no leads; 14 terminals; body $3\times4.5\times0.85$ mm	SOT1086-2						
TJA1145ATK/FD	HVSON14	plastic thermal enhanced very thin small outline package; no leads; 14 terminals; body $3\times4.5\times0.85$ mm	SOT1086-2						

# 5. Block diagram



#### **Pinning information** 6.

#### 6.1 **Pinning**



### 6.2 Pin description

Symbol	Pin	Description			
TXD	1	transmit data input			
GND	2[1]	ground			
VCC	3	5 V CAN transceiver supply voltage			
RXD	4	receive data output; reads out data from the bus lines			
VIO	5	supply voltage for I/O level adaptor			
SDO	6	SPI data output			
INH	7	inhibit output for switching external voltage regulators			
SCK	8	SPI clock input			
WAKE	9	local wake-up input			
BAT	10	battery supply voltage			
SDI	11	SPI data input			
CANL	12	LOW-level CAN bus line			
CANH	13	HIGH-level CAN bus line			
SCSN	14	SPI chip select input			

[1] HVSON14 package die supply ground is connected to both the GND pin and the exposed center pad. The GND pin must be soldered to board ground. For enhanced thermal and electrical performance, it is recommended that the exposed center pad also be soldered to board ground

# 7. Functional description

The TJA1145A is a stand-alone high-speed CAN transceiver containing a variety of fail-safe and diagnostic features that offer enhanced system reliability and advanced power management. The transceiver combines the functionality of the TJA1043 with ISO 11898-2:2016 compliant CAN partial networking and autonomous bus biasing.

### 7.1 System controller

The system controller manages register configuration and controls the internal functions of the TJA1145A. Detailed device status information is collected and made available to the microcontroller.

### 7.1.1 Operating modes

The system controller contains a state machine that supports five operating modes: Normal, Standby, Sleep, Overtemp and Off. The state transitions are illustrated in Figure 4.

### 7.1.1.1 Normal mode

Normal mode is the active operating mode. In this mode, the TJA1145A is fully operational. All device hardware is available and can be activated (see <u>Table 4</u>).

Normal mode can be selected from Standby or Sleep mode via an SPI command (MC = 111).

### 7.1.1.2 Standby mode

Standby mode is the first-level power-saving mode of the TJA1145A, featuring low current consumption. The transceiver is unable to transmit or receive data in Standby mode, but the INH pin remains active so voltage regulators controlled by this pin will be active.

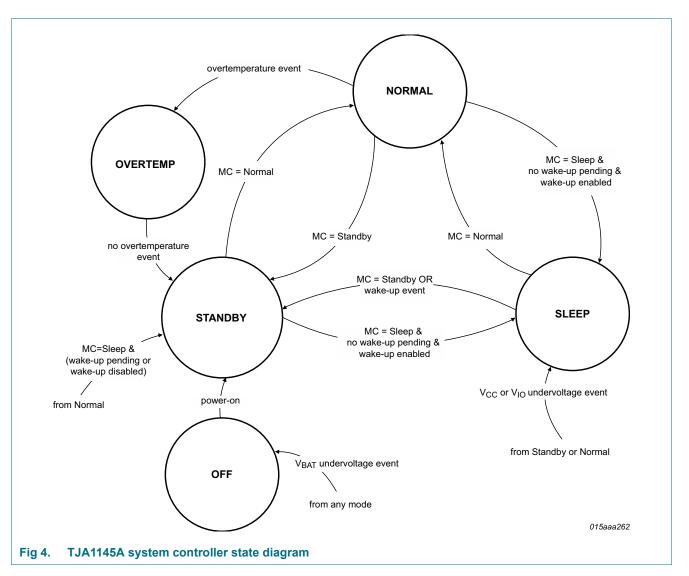
If remote CAN wake-up is enabled (CWE = 1; see <u>Table 22</u>), the receiver monitors bus activity for a wake-up request. The bus pins are biased to GND (via  $R_{i(cm)}$ ) when the bus is inactive and at approximately 2.5 V when there is activity on the bus (autonomous biasing). CAN wake-up can occur via a standard wake-up pattern or via a selective wake-up frame (selective wake-up is enabled when CPNC = PNCOK = 1; otherwise standard wake-up is enabled).

Pin RXD is forced LOW when any enabled wake-up or interrupt event is detected (see <u>Section 7.6</u>).

The TJA1145A switches to Standby mode:

- from Off mode if the battery voltage rises above the power-on detection threshold,  $V_{th(det)pon}$ .
- from Overtemp mode if the chip temperature falls below the overtemperature protection release threshold, T<sub>th(rel)otp</sub>.
- from Sleep mode on the occurrence of a wake-up or interrupt event (see Section 7.6)
- from Normal or Sleep mode via an SPI command (MC = 100)
- from Normal mode if Sleep mode is selected via an SPI command (MC = 001) while a wake-up event is pending or all wake-up sources are disabled

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#### 7.1.1.3 Sleep mode

Sleep mode is the second-level power saving mode of the TJA1145A. In Sleep mode, the transceiver behaves as in Standby Mode with the exception that pin INH is set to a high-ohmic state. Voltage regulators controlled by this pin will be switched off, and the current into pin BAT will be reduced to a minimum.

Any enabled wake-up or interrupt event (except SPIF), or an SPI command (provided a valid  $V_{IO}$  voltage is connected), will wake up the transceiver from Sleep mode.

Sleep mode can be selected from Normal or Standby mode via an SPI command (MC = 001). The TJA1145A will switch to Sleep mode on receipt of this command, provided there are no pending wake-up events and at least one regular wake-up source (CAN bus or WAKE pin; see Section 7.6) is enabled. Any attempt to enter Sleep mode while one of these conditions has not been met will cause the TJA1145A to switch to Standby mode.

The TJA1145A will also be forced to switch to Sleep mode after  $t_{d(uvd-sleep)}$  if a V<sub>CC</sub> of V<sub>IO</sub> undervoltage event is detected (V<sub>CC</sub>/V<sub>IO</sub> < V<sub>uvd(VCC)</sub>/V<sub>uvd(VIO)</sub> for longer than  $t_{d(uvd)}$ ). In this event, all pending wake-up events will be cleared. CAN wake-up (CWE = 1) and local wake-up via the WAKE pin (WPFE = WPRE = 1) are enabled in order to avoid a system deadlock (see Section 7.11) and selective wake-up is disabled (CPNC = 0).

Status bit FSMS in the Main status register (Table 6) indicates whether a transition to Sleep mode was selected via an SPI command (FSMS = 0) or was forced by an undervoltage event on VCC or VIO (FSMS = 1). This bit can be read after the TJA1145A wakes up from Sleep mode to allow the settings of CWE, WPFE, WPRE and CPNC to be re-adjusted if an undervoltage event forced the transition to Sleep mode (FSMS = 1).

### 7.1.1.4 Off mode

The TJA1145A will be in Off mode when the battery voltage is too low to supply the IC. This is the default mode when the battery is first connected. The TJA1145A will switch to Off mode from any mode if the battery voltage drops below the power-off threshold  $(V_{th(det)poff})$ . In Off mode, the CAN pins and pin INH are in a high-ohmic state.

When the battery supply voltage rises above the power-on threshold ( $V_{th(det)pon}$ ), the TJA1145A starts to boot up, triggering an initialization procedure. The TJA1145A will switch to Standby mode after  $t_{startup}$ .

### 7.1.1.5 Overtemp mode

Overtemp mode is provided to prevent TJA1145A being damaged by excessive temperatures. The TJA1145A switches immediately to Overtemp mode from Normal mode when the global chip temperature rises above the overtemperature protection activation threshold,  $T_{th(act)otp}$ .

To help prevent the loss of data due to overheating, the TJA1145A issues a warning when the IC temperature rises above the overtemperature warning threshold ( $T_{th(warn)otp}$ ). When this happens, status bit OTWS is set and an overtemperature interrupt is generated (OTW = 1), if enabled (OTWE = 1).

In Overtemp mode, the CAN transmitter and receiver are disabled and the CAN pins are in a high-ohmic state. Wake-up events will not be detected, but a pending wake-up will still be signalled by a LOW level on pin RXD, which will persist after the overtemperature event has been cleared.

The TJA1145A exits Overtemp mode:

- and switches to Standby mode if the chip temperature falls below the overtemperature protection release threshold, T<sub>th(rel)otp</sub>
- if the device is forced to switch to Off mode (V<sub>BAT</sub> < V<sub>th(det)poff</sub>)

#### 7.1.1.6 Hardware characterization for the TJA1145A operating modes

 Table 4.
 Hardware characterization by functional block

Block	Operating n	Operating mode									
	Off	Standby	Normal	Sleep	Overtemp						
SPI	disabled	active	active	active if V <sub>IO</sub> supplied <sup>[1]</sup>	disabled						
INH	high-ohmic	V <sub>BAT</sub> level	V <sub>BAT</sub> level	high-ohmic	V <sub>BAT</sub> level						
CAN	off	Offline	Active/ Offline/ Listen-only (determined by bits CMC; see <u>Table 7</u> )	Offline	off						
RXD	V <sub>IO</sub> level	V <sub>IO</sub> level/LOW if wake-up event detected	CAN bit stream if CMC = 01/10/11; otherwise same as Standby/Sleep	V <sub>IO</sub> level/LOW if wake-up event detected	V <sub>IO</sub> level/LOW if wake-up pending						

[1] SPI speed is limited in Sleep mode (see Table 35).

### 7.1.2 System control registers

The operating mode is selected via bits MC in the Mode control register. The Mode control register is accessed via SPI address 0x01 (see <u>Section 7.12</u>).

				,
Bit	Symbol	Access	Value	Description
7:3	reserved	R	-	
2:0	MC	R/W		mode control:
			001	Sleep mode
			100	Standby mode
			111	Normal mode

#### Table 5. Mode control register (address 01h)

The Main status register can be accessed to monitor the status of the overtemperature warning flag and to determine whether the TJA1145A has entered Normal mode after initial power-up. Bit FSMS indicates whether the most recent transition to Sleep mode was triggered by an undervoltage event or by an SPI command.

#### Table 6. Main status register (address 03h)

Bit	Symbol	Access	Value	Description
7	FSMS	6 R		Sleep mode transition status:
			0	transition to Sleep mode triggered by an SPI command
			1	an undervoltage on VCC and/or VIO forced a transition to Sleep mode
6	OTWS R	R		overtemperature warning status:
			0	IC temperature below overtemperature warning threshold
			1	IC temperature above overtemperature warning threshold
5	NMS	R		Normal mode status:
			0	TJA1145A has entered Normal mode (after power-up)
			1	TJA1145A has powered up but has not yet switched to Normal mode
4:0	reserved	R	-	

### 7.2 High-speed CAN transceiver

The integrated high-speed CAN transceiver is designed for active communication at bit rates up to 1 Mbit/s, providing differential transmit and receive capability to a CAN protocol controller. The transceiver is ISO 11898-2:2016 compliant (defining high-speed CAN with selective wake-up functionality and autonomous bus biasing). The CAN transmitter is supplied via pin VCC while the CAN receiver is supplied via pin BAT. The TJA1145A includes additional timing parameters on loop delay symmetry to ensure reliable communication in fast phase at data rates up to 5 Mbit/s, as used in CAN FD networks.

The CAN transceiver supports autonomous CAN biasing, which helps to minimize RF emissions. CANH and CANL are always biased to 2.5 V when the transceiver is in Active or Listen-only modes (CMC = 01/10/11).

Autonomous biasing is active in CAN Offline mode - to 2.5 V if there is activity on the bus (CAN Offline Bias mode) and to GND if there is no activity on the bus for t >  $t_{to(silence)}$  (CAN Offline mode).

This is useful when the node is disabled due to a malfunction in the microcontroller or when CAN partial networking is enabled. The TJA1145A ensures that the CAN bus is correctly biased to avoid disturbing ongoing communication between other nodes. The autonomous CAN bias voltage is derived directly from  $V_{BAT}$ .

### 7.2.1 CAN operating modes

The integrated CAN transceiver supports four operating modes: Active, Listen-only, Offline and Offline Bias (see <u>Figure 5</u>). The CAN transceiver operating mode depends on the TJA1145A operating mode and on the setting of bits CMC in the CAN control register (<u>Table 7</u>).

When the TJA1145A is in Normal mode, the CAN transceiver operating mode (Offline, Active or Listen-only) can be selected via bits CMC in the CAN control register (<u>Table 7</u>). When the TJA1145A is in Standby or Sleep modes, the transceiver is forced to Offline or Offline Bias mode (depending on bus activity).

### 7.2.1.1 CAN Active mode

In CAN Active mode, the transceiver can transmit and receive data via CANH and CANL. The differential receiver converts the analog data on the bus lines into digital data, which is output on pin RXD. The transmitter converts digital data generated by the CAN controller (input on pin TXD) into analog signals suitable for transmission over the CANH and CANL bus lines.

CAN Active mode is selected when CMC = 01 or 10. When CMC = 01, V<sub>CC</sub> undervoltage detection is enabled and the transceiver switches to CAN Offline or CAN Offline Bias mode when the voltage on V<sub>CC</sub> drops below V<sub>uvd(VCC)</sub>. When CMC = 10, V<sub>CC</sub> undervoltage detection is disabled. The transmitter will remain active until the TJA1145A is forced into Sleep mode by the V<sub>CC</sub> undervoltage event; the transceiver will then switch to CAN Offline or CAN Offline Bias mode.

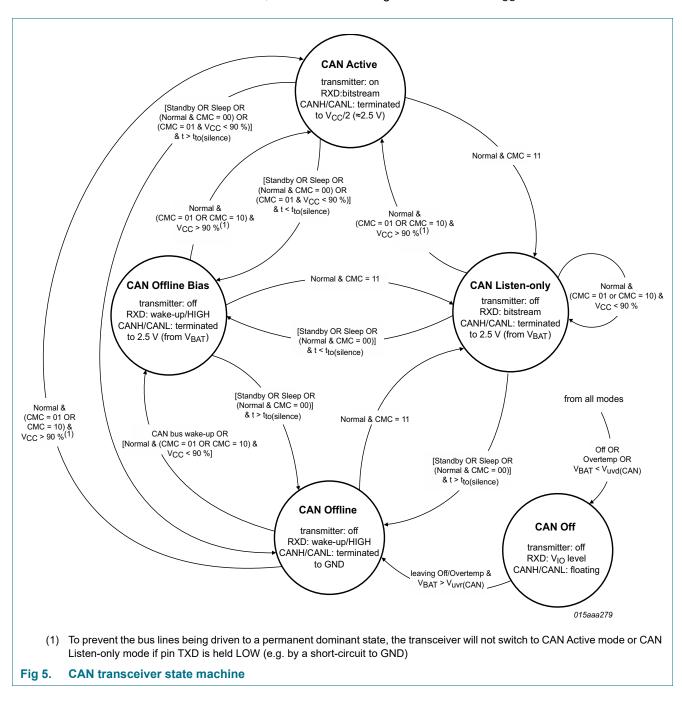
The CAN transceiver is in Active mode when:

 the TJA1145A is in Normal mode (MC = 111) and the CAN transceiver has been enabled by setting bits CMC in the CAN control register to 01 or 10 (see Table 7) and:

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 if CMC = 01, the voltage on pin VCC is above the V<sub>CC</sub> undervoltage detection threshold (V<sub>uvd(VCC)</sub>)

If pin TXD is held LOW (e.g. by a short-circuit to GND) when CAN Active mode is selected via bits CMC, the transceiver will not enter CAN Active mode but will switch to or remain in CAN Listen-only mode. It will remain in Listen-only mode until pin TXD goes HIGH in order to prevent a hardware and/or software application failure from driving the bus lines to an unwanted dominant state.



In CAN Active mode, the CAN bias voltage is derived from V<sub>CC</sub>.

The application can determine whether the CAN transceiver is ready to transmit/receive data or is disabled by reading the CAN Transceiver Status (CTS) bit in the Transceiver Status Register (Table 8).

#### 7.2.1.2 CAN Listen-only mode

CAN Listen-only mode allows the TJA1145A to monitor bus activity while the transceiver is inactive, without influencing bus levels. This facility could be used by development tools that need to listen to the bus but do not need to transmit or receive data or for software-driven selective wake-up. Dedicated microcontrollers could be used for selective wake-up, providing an embedded low-power CAN engine designed to monitor the bus for potential wake-up events.

In Listen-only mode the CAN transmitter is disabled, reducing current consumption. The CAN receiver and CAN biasing remain active. This enables the host microcontroller to switch to a low-power mode in which an embedded CAN protocol controller remains active, waiting for a signal to wake up the microcontroller.

The CAN transceiver is in Listen-only mode when:

• the TJA1145A is in Normal mode and CMC = 11

The CAN transceiver will not leave Listen-only mode while TXD is LOW or CAN Active mode is selected with CMC = 01 or 10 while the voltage on VCC is below the undervoltage threshold,  $V_{uvd(VCC)}$ .

#### 7.2.1.3 CAN Offline and Offline Bias modes

In CAN Offline mode, the transceiver monitors the CAN bus for a wake-up event, provided CAN wake-up detection is enabled (CWE = 1). CANH and CANL are biased to GND.

CAN Offline Bias mode is the same as CAN Offline mode, with the exception that the CAN bus is biased to 2.5 V. This mode is activated automatically when activity is detected on the CAN bus while the transceiver is in CAN Offline mode. The transceiver will return to CAN Offline mode if the CAN bus is silent (no CAN bus edges) for longer than  $t_{to(silence)}$ .

The CAN transceiver switches to CAN Offline mode from CAN Active mode or CAN Listen-only mode if:

- the TJA1145A switches to Standby or Sleep mode OR
- the TJA1145A is in Normal mode and CMC = 00

provided the CAN-bus has been inactive for at least  $t_{to(silence)}$ . If the CAN-bus has been inactive for less than  $t_{to(silence)}$ , the CAN transceiver switches first to CAN Offline Bias mode and then to CAN Offline mode once the bus has been silent for  $t_{to(silence)}$ .

The CAN transceiver switches to CAN Offline/Offline Bias mode from CAN Active mode if CMC = 01 and the voltage on VCC drops below the undervoltage threshold or if CMC = 10 and the TJA1145A switches to Sleep mode in response to a  $V_{CC}$  undervoltage event.

The CAN transceiver switches to CAN Offline mode:

 from CAN Offline Bias mode if no activity is detected on the bus (no CAN edges) for t > t<sub>to(silence)</sub> OR

• when the TJA1145A switches from Off or Overtemp mode to Standby mode

The CAN transceiver switches from CAN Offline mode to CAN Offline Bias mode if:

- a standard wake-up pattern is detected on the CAN bus OR
- the CAN transceiver is in Normal mode, CMC = 01 or 10 and V<sub>CC</sub> < 90 %

#### 7.2.1.4 CAN Off mode

The CAN transceiver is switched off completely with the bus lines floating when:

- the TJA1145A switches to Off or Overtemp mode OR
- V<sub>BAT</sub> falls below the CAN receiver undervoltage detection threshold, V<sub>uvd(CAN)</sub>

It will be switched on again on entering CAN Offline mode when  $V_{BAT}$  rises above the undervoltage recovery threshold ( $V_{uvr(CAN)}$ ) and the CAN transceiver is no longer in Off/Overtemp mode. CAN Off mode prevents reverse currents flowing from the bus when the battery supply to the CAN transceiver is lost.

### 7.2.2 CAN standard wake-up (partial networking not enabled)

If the CAN transceiver is in Offline mode and CAN wake-up is enabled (CWE = 1), but CAN selective wake-up is disabled (CPNC = 0 or PNCOK = 0), the TJA1145A will monitor the bus for a standard wake-up pattern.

A filter at the receiver input prevents unwanted wake-up events occurring due to automotive transients or EMI. This filtering helps avoid spurious wake-up events. A spurious wake-up sequence could be triggered by, for example, a dominant clamped bus or by dominant phases due to noise or spikes on the bus.

The TJA1145A wakes up from Standby or Sleep mode when a dedicated wake-up pattern (specified in ISO 11898-2:2016) is detected on the bus.

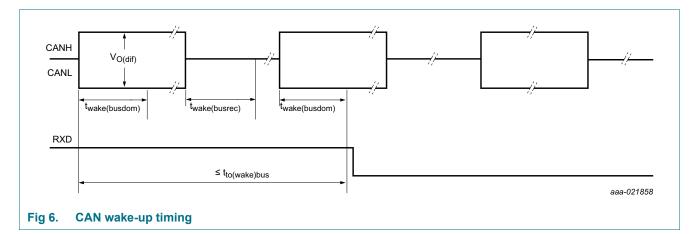
The wake-up pattern consists of:

- a dominant phase of at least t<sub>wake(busdom)</sub> followed by
- a recessive phase of at least t<sub>wake(busrec)</sub> followed by
- a dominant phase of at least twake(busdom)

Dominant or recessive bits between the above mentioned phases that are shorter than  $t_{wake(busdom)}$  and  $t_{wake(busrec)}$  respectively are ignored.

The complete dominant-recessive-dominant pattern must be received within  $t_{to(wake)bus}$  to be recognized as a valid wake-up pattern (see <u>Figure 6</u>). Otherwise, the internal wake-up logic is reset. The complete wake-up pattern will then need to be retransmitted to trigger a wake-up event. Pin RXD remains HIGH until the wake-up event has been triggered.

When a valid CAN wake-up pattern is detected on the bus, wake-up bit CW in the Transceiver event status register is set (see <u>Table 19</u>) and pin RXD is driven LOW. If the TJA1145A was in Sleep mode when the wake-up pattern was detected, it will switch pin INH to  $V_{BAT}$  to activate external voltage regulators (e.g. for supplying  $V_{CC}$  and  $V_{IO}$ ) and enter Standby mode.



## 7.2.3 CAN control and Transceiver status registers

Bit	Symbol	Access	Value	Description
7	reserved	R	-	
6	CFDC	R/W		CAN FD tolerance (TJA1145Ax/FD variants only; otherwise ignored)
			0	CAN FD tolerance disabled
			1	CAN FD tolerance enabled
5	PNCOK	R/W		CAN partial networking configuration:
			0	partial networking register configuration invalid (wake-up via standard wake-up pattern only)
			1	partial networking registers configured successfully
4	CPNC	R/W		CAN selective wake-up; when enabled, node is part of a partial network:
			0	disable CAN selective wake-up
			1	enable CAN selective wake-up
3:2	reserved	R	-	
1:0	CMC	R/W		CAN transceiver operating mode selection:
			00	Offline mode
			01	$\begin{array}{c} \mbox{Active mode (while TJA1145A is in Normal mode);} \\ V_{CC} \mbox{ undervoltage detection active; transition to} \\ \mbox{Active mode, and remaining in Active mode,} \\ \mbox{ requires } V_{CC} \mbox{ above undervoltage threshold} \end{array}$
			10	$\begin{array}{c} \mbox{Active mode (while TJA1145A is in Normal mode);} \\ V_{CC} \mbox{ undervoltage detection inactive; transition to} \\ \mbox{Active mode requires } V_{CC} \mbox{ above undervoltage} \\ \mbox{threshold} \end{array}$
			11	Listen-only mode

#### Table 7. CAN control register (address 20h)

Bit	Symbol	Access	Value	Description
7	CTS	R		CAN transceiver status:
			0	CAN transceiver not in Active mode
			1	CAN transceiver in Active mode
6	CPNERR	R		CAN partial networking error status:
			0	no CAN partial networking error detected (PNFDE = 0 AND PNCOK = 1)
			1	CAN partial networking error detected (PNFDE = 1 OR PNCOK = 0); wake-up via standard wake-up pattern only
5	CPNS	R		CAN partial networking status:
			0	CAN partial networking configuration error detected (PNCOK = 0)
			1	CAN partial networking configuration OK (PNCOK = 1)
4	COSCS	R		CAN oscillator status:
			0	CAN partial networking oscillator not running at target frequency
			1	CAN partial networking oscillator running at target frequency
3	CBSS	R		CAN bus silence status:
			0	CAN bus active (communication detected on bus)
			1	CAN bus inactive (for longer than $t_{\text{to}(\text{silence})}$
2	reserved	R	-	
1	VCS <sup>[1]</sup>	R		V <sub>CC</sub> supply voltage status:
			0	$V_{CC}$ is above the undervoltage detection threshold $(V_{uvd(VCC)})$
			1	$V_{CC}$ is below the undervoltage detection threshold $(V_{uvd(VCC)})$
0	CFS	R		CAN failure status:
			0	no TXD dominant time-out event detected
			1	CAN transmitter disabled due to a TXD dominant time-out event

### Table 8.Transceiver status register (address 22h)

[1] Only active when CMC = 01.

### 7.3 CAN partial networking

Partial networking allows nodes in a CAN network to be selectively activated in response to dedicated wake-up frames (WUF). Only nodes that are functionally required are active on the bus while the other nodes remain in a low-power mode until needed.

If both CAN wake-up (CWE = 1) and CAN selective wake-up (CPNC = 1) are enabled, and the partial networking registers are configured correctly (PNCOK = 1), the transceiver monitors the bus for dedicated CAN wake-up frames.

### 7.3.1 Wake-up frame (WUF)

A wake-up frame is a CAN frame according to ISO 11898-1:2015, consisting of an identifier field (ID), a Data Length Code (DLC), a data field and a Cyclic Redundancy Check (CRC) code including the CRC delimiter.

The wake-up frame format, standard (11-bit) or extended (29-bit) identifier, is selected via bit IDE in the Frame control register (<u>Table 12</u>).

A valid WUF identifier is defined and stored in the ID registers (<u>Table 10</u>). An ID mask can be defined to allow a group of identifiers to be recognized as valid by an individual node. The identifier mask is defined in the mask registers (<u>Table 11</u>), where a 1 means 'don't care'.

In the example illustrated in Figure 7, based on the standard frame format, the 11-bit identifier is defined as 0x1A0. The identifier is stored in ID registers 2 (0x29) and 3 (0x2A). The three least significant bits of the ID mask, bits 2 to 4 of Mask register 2 (0x2D) are set to 1, which means that the corresponding identifier bits are 'don't care'. This means that any of eight different identifiers will be recognized as valid in the received WUF (from 0x1A0 to 0x1A7).

0x1A0 stored in ID registers 2 and 3	0	0	1	1	0	1	0	0	0	0	0
ID mask: 0x007 stored in Mask registers 2 and 3	0	0	0	0	0	0	0	0	1	1	1
registers 2 and 3	L	1	1	•							
alid Wake-Up Identii	iers: 0>	:1A0 to 0	x1A7								

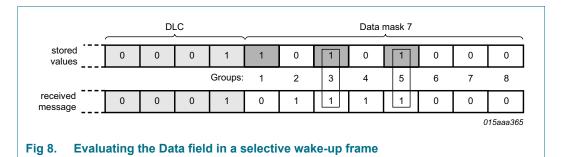
The data field indicates which nodes are to be woken up. Within the data field, groups of nodes can be pre-defined and associated with bits in a data mask. By comparing the incoming data field with the data mask, multiple groups of nodes can be woken up simultaneously with a single wake-up message.

The data length code (bits DLC in the Frame control register; <u>Table 12</u>) determines the number of data bytes (between 0 and 8) expected in the data field of a CAN wake-up frame. If one or more data bytes are expected (DLC  $\neq$  0000), at least one bit in the data field of the received wake-up frame must be set to 1 and at least one equivalent bit in the associated data mask register in the transceiver (see <u>Table 13</u>) must also be set to 1 for a successful wake-up. Each matching pair of 1s indicates a group of nodes to be activated (since the data field is up to 8 byes long, up to 64 groups of nodes can be defined).

If DLC = 0000, a node will wake up if the WUF contains a valid identifier and the received data length code is 0000, regardless of the values stored in the data mask. If DLC  $\neq$  0000 and all data mask bits are set to 0, the device cannot be woken up via the CAN bus (note that all data mask bits are set to 1 by default; see <u>Table 31</u>). If a WUF contains a valid ID but the DLCs (in the Frame control register and in the WUF) don't match, the data field is ignored and no nodes are woken up.

In the example illustrated in Figure 8, the data field consists of a single byte (DLC = 1). This means that the data field in the incoming wake-up frame is evaluated against data mask 7 (stored at address 6Fh; see Table 13 and Figure 9). Data mask 7 is defined as 10101000 in the example. This means that up to three groups of nodes could be woken up (group 1, 3 and 5) if the respective bits in the data frame are also set to 1.

The received message shown in <u>Figure 8</u> could, potentially, wake up four groups of nodes: groups 2, 3, 4 and 5. Two matches are found (groups 3 and 5) when the message data bits are compared with the configured data mask (DM7).



Optionally, the data length code and the data field can be excluded from the evaluation of the wake-up frame. If bit PNDM = 0, only the identifier field is evaluated to determine if the frame contains a valid wake-up message. If PNDM = 1 (the default value), the data field is included in the wake-up filtering.

When PNDM = 0, a valid wake-up message is detected and a wake-up event is captured (and CW is set to 1) when:

- the identifier field in the received wake-up frame matches the pattern in the ID registers after filtering AND
- the CRC field in the received frame (including a recessive CRC delimiter) was received without error

When PNDM = 1, a valid wake-up message is detected when:

- the identifier field in the received wake-up frame matches the pattern in the ID registers after filtering AND
- the frame is not a Remote frame AND

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- the data length code in the received message matches the configured data length code (bits DLC) AND
- if the data length code is greater than 0, at least one bit in the data field of the received frame is set and the corresponding bit in the associated data mask register is also set AND
- the CRC field in the received frame (including a recessive CRC delimiter) was received without error

If the TJA1145A receives a CAN message containing errors (e.g. a 'stuffing' error) transmitted in advance of the ACK field, an internal error counter is incremented. If a CAN message is received without any errors appearing in front of the ACK field, the counter is decremented. Data received after the CRC delimiter and before the next SOF is ignored by the partial networking module. If the counter overflows (counter > 31), a frame detect error is captured (PNFDE = 1) and the device wakes up; the counter is reset to zero when the bias is switched off and partial networking is re-enabled.

Partial networking is assumed to be configured correctly when PNCOK is set to 1 by the application software. The TJA1145A clears PNCOK after a write access to any of the CAN partial networking configuration registers (see <u>Section 7.3.3</u>).

If selective wake-up is disabled (CPNC = 0) or partial networking is not configured correctly (PNCOK = 0), and the CAN transceiver is in Offline mode with wake-up enabled (CWE = 1), then any valid wake-up pattern (according to ISO 11898-2:2016) will trigger a wake-up event.

If the CAN transceiver is not in Offline mode (CMC  $\neq$  00) or CAN wake-up is disabled (CWE = 0), all wake-up patterns on the bus will be ignored.

CAN bit rates of 50 kbit/s, 100 kbit/s, 125 kbit/s, 250 kbit/s, 500 kbit/s and 1 Mbit/s are supported during selective wake-up. The bit rate is selected via bits CDR (see <u>Table 9</u>).

### 7.3.2 CAN FD frames

CAN FD stands for 'CAN with Flexible Data-Rate'. It is based on the CAN protocol as specified in ISO 11898-1:2015.

CAN FD is being gradually introduced into the automotive market. In time, all CAN controllers will be required to comply with the new standard (enabling 'FD-active' nodes) or at least to tolerate CAN FD communication (enabling 'FD-passive' nodes). The TJA1145Ax/FD variants support FD-passive features by means of a dedicated implementation of the partial networking protocol.

These variants can be configured to recognize CAN FD frames as valid frames. When CFDC = 1, the error counter is decremented every time the control field of a CAN FD frame is received. The TJA1145Ax/FD remains in low-power mode (CAN FD-passive) with partial networking enabled. CAN FD frames are never recognized as valid wake-up frames, even if PNDM = 0 and the frame contains a valid ID. After receiving the control field of a CAN FD frame, the TJA1145Ax/FD ignores further bus signals until idle is again detected.

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CAN FD passive is supported up to a ratio of one-to-eight between arbitration and data bit rates, without unwanted wake-ups. The CAN FD filter parameter defined in ISO 11898-2:2016 and SAE J2284 is supported up to a ratio of one-to-four, with a maximum supported bit data bit rate of 2 Mbit/s and a maximum arbitration speed of 500 kbit/s.

CAN FD frames are interpreted as frames with errors by the partial networking module in the TJA1145AT and TJA1145ATK, and in the TJA1145Ax/FD variants when CFDC = 0. So the error counter is incremented when a CAN FD frame is received. If the ratio of CAN FD frames to valid CAN frames exceeds the threshold that triggers error counter overflow, bit PNFDE is set to 1 and the device wakes up.

### 7.3.3 CAN partial networking configuration registers

Dedicated registers are provided for configuring CAN partial networking.

Bit	Symbol	Access	Value	Description
7:3	reserved	R	-	
2:0	CDR	R/W		CAN data rate selection:
			000	50 kbit/s
			001	100 kbit/s
			010	125 kbit/s
			011	250 kbit/s
			100	reserved (intended for future use; currently selects 500 kbit/s)
			101	500 kbit/s
			110	reserved (intended for future use; currently selects 500 kbit/s)
			111	1000 kbit/s

#### Table 9. Data rate register (address 26h)

#### Table 10. ID registers 0 to 3 (addresses 27h to 2Ah)

Addr.	Bit	Symbol	Access	Value	Description
27h	7:0	ID7:ID0	R/W	-	bits ID7 to ID0 of the extended frame format
28h	7:0	ID15:ID08	R/W	-	bits ID15 to ID8 of the extended frame format
29h	7:2	ID23:ID18	R/W	-	bits ID23 to ID18 of the extended frame format bits ID5 to ID0 of the standard frame format
	1:0	ID17:ID16	R/W	-	bits ID17 to ID16 of the extended frame format
2Ah	7:5	reserved	R	-	
	4:0	ID28:ID24	R/W	-	bits ID28 to ID24 of the extended frame format bits ID10 to ID6 of the standard frame format

#### Table 11. ID mask registers 0 to 3 (addresses 2Bh to 2Eh)

Addr.	Bit	Symbol	Access	Value	Description
2Bh	7:0	M7:M0	R/W	-	ID mask bits 7 to 0 of extended frame format
2Ch	7:0	M15:M8	R/W	-	ID mask bits 15 to 8 of extended frame format

		•			
Addr.	Bit	Symbol	Access	Value	Description
2Dh	7:2	M23:M18	R/W	-	ID mask bits 23 to 18 of extended frame format ID mask bits 5 to 0 of standard frame format
	1:0	M17:M16	R/W	-	ID mask bits 17 to 16 of extended frame format
2Eh	7:5	reserved	R	-	
	4:0	M28:M24	R/W	-	ID mask bits 28 to 24 of extended frame format ID mask. bits 10 to 6 of standard frame format

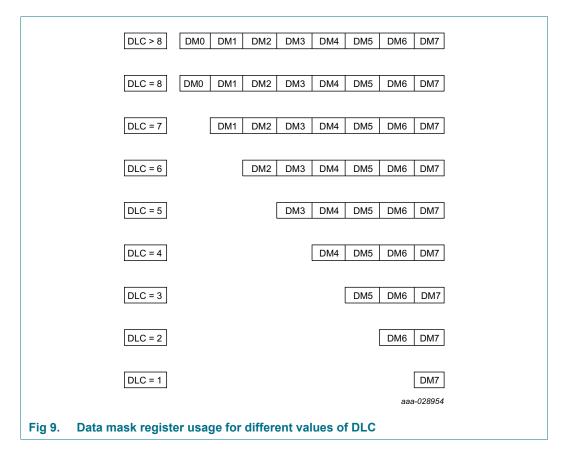
#### Table 11. ID mask registers 0 to 3 (addresses 2Bh to 2Eh) ...continued

#### Table 12. Frame control register (address 2Fh)

Bit	Symbol	Access	Value	Description
7	IDE	R/W	-	identifier format:
			0	standard frame format (11-bit)
			1	extended frame format (29-bit)
6	PNDM	R/W	-	partial networking data mask:
			0	data length code and data field are 'don't care' for wake-up
			1	data length code and data field are evaluated at wake-up
5:4	reserved	R	-	
3:0	DLC	R/W		number of data bytes expected in a CAN frame:
			0000	0
			0001	1
			0010	2
			0011	3
			0100	4
			0101	5
			0110	6
			0111	7
			1000	8
			1001 to 1111	tolerated, 8 bytes expected

#### Table 13. Data mask registers (addresses 68h to 6Fh)

		-	•		
Addr.	Bit	Symbol	Access	Value	Description
68h	7:0	DM0	R/W	-	data mask 0 configuration
69h	7:0	DM1	R/W	-	data mask 1 configuration
6Ah	7:0	DM2	R/W	-	data mask 2 configuration
6Bh	7:0	DM3	R/W	-	data mask 3 configuration
6Ch	7:0	DM4	R/W	-	data mask 4 configuration
6Dh	7:0	DM5	R/W	-	data mask 5 configuration
6Eh	7:0	DM6	R/W	-	data mask 6 configuration
6Fh	7:0	DM7	R/W	-	data mask 7 configuration



### 7.4 Fail-safe features

### 7.4.1 TXD dominant time-out

A TXD dominant time-out timer is started when pin TXD is forced LOW while the transceiver is in Active Mode. If the LOW state on pin TXD persists for longer than the TXD dominant time-out time ( $t_{to(dom)TXD}$ ), the transmitter is disabled, releasing the bus lines to recessive state. This function prevents a hardware and/or software application failure from driving the bus lines to a permanent dominant state (blocking all network communications). The TXD dominant time-out time ris reset when pin TXD goes HIGH. The TXD dominant time-out time also defines the minimum possible bit rate of 15 kbit/s.

When the TXD dominant time-out time is exceeded, a CAN failure interrupt is generated (CF = 1; see <u>Table 19</u>), if enabled (CFE = 1; see <u>Table 22</u>). In addition, the status of the TXD dominant time-out can be read via the CFS bit in the Transceiver status register (<u>Table 8</u>) and bit CTS is set to 0.

### 7.4.2 Pull-up on TXD pin

Pin TXD has an internal pull-up towards  $V_{IO}$  to ensure a safe defined recessive driver state in case the pin is left floating.

### 7.4.3 V<sub>CC</sub> undervoltage event

When CMC = 01 and the supply to the CAN transceiver ( $V_{CC}$ ) falls below  $V_{uvd(VCC)}$ , a CAN failure event is captured (CF = 1), assuming CAN failure detection is enabled (CFE = 1), and status bit VCS is set to 1.

### 7.4.4 Loss of power at pin BAT

A loss of power at pin BAT has no influence on the bus lines or on the microcontroller. No reverse currents will flow from the bus.

### 7.5 Local wake-up via WAKE pin

Local wake-up is enabled via bits WPRE and WPFE in the WAKE pin event capture enable register (see <u>Table 23</u>). A wake-up event is triggered by a LOW-to-HIGH (if WPRE = 1) and/or a HIGH-to-LOW (if WPFE = 1) transition on the WAKE pin. This arrangement allows for maximum flexibility when designing a local wake-up circuit. In applications that don't make use of the local wake-up facility, local wake-up should be disabled and the WAKE pin connected to GND to ensure optimal EMI performance.

Bit	Symbol	Access	Value	Description
7:2	reserved	R	-	
1	WPVS	R		WAKE pin status:
			0	voltage on WAKE pin below switching threshold $(V_{th(sw)})$
			1	voltage on WAKE pin above switching threshold $(V_{th(sw)})$
0	reserved	R	-	

#### Table 14. WAKE status register (address 4Bh)

While the TJA1145A is in Normal mode, the status of the voltage on pin WAKE can always be read via bit WPVS. Otherwise, WPVS is only valid if local wake-up is enabled (WPRE = 1 and/or WPFE = 1).

### 7.6 Wake-up and interrupt event diagnosis via pin RXD

Wake-up and interrupt event diagnosis in the TJA1145A is intended to provide the microcontroller with information on the status of a range of features and functions. This information is stored in the event status registers (<u>Table 18</u> to <u>Table 20</u>) and is signaled on pin RXD pin, if enabled.

A distinction is made between regular wake-up events and interrupt events (at least one regular wake-up source must be enabled to allow the TJA1145A to switch to Sleep mode; see Section 7.1.1.3).

Symbol	Event	Power-on	Description
CW	CAN wake-up	disabled	a CAN wake-up event was detected while the transceiver was in CAN Offline mode.
WPR	rising edge on WAKE pin	disabled	a rising-edge wake-up was detected on pin WAKE
WPF	falling edge on WAKE pin	disabled	a falling-edge wake-up was detected on pin WAKE

Table 15. Regular wake-up events

Symbol	Event	Power-on	Description
PO	power-on	always enabled	the TJA1145A has exited Off mode (after battery power has been restored/connected)
OTW	overtemperature warning	disabled	the IC temperature has exceeded the overtemperature warning threshold (only detected in Normal mode)
SPIF	SPI failure	disabled	SPI clock count error (only 16-, 24- and 32-bit commands are valid), illegal MC code or attempted write access to locked register (an SPI failure event will not wake-up the TJA1145A from Sleep mode)
PNFDE	PN frame detection error	always enabled	partial networking frame detection error
CBS	CAN bus silence	disabled	no activity on CAN bus for $t_{to(silence)}$ (detected only when CBSE = 1 while bus active)
CF	CAN failure	disabled	one of the following CAN failure events detected (not is Sleep mode):
			- CAN transceiver deactivated due to a dominant clamped TXD
			- CAN transceiver deactivated due to a V <sub>CC</sub> undervoltage event (if CMC = 01)

#### Table 16. Interrupt events

PO and PNFDE interrupts are always captured. Wake-up and interrupt detection can be enabled/disabled for the remaining events individually via the event capture enable registers (Table 21 to Table 23).

If an event occurs while the associated event capture function is enabled, the relevant event status bit is set. If the transceiver is in CAN Offline mode, pin RXD is forced LOW to indicate that a wake-up or interrupt event has been detected. If the TJA1145A is in Sleep mode when an event (other than a SPIF interrupt) occurs, pin INH is forced HIGH and the TJA1145A switches to Standby mode. If the TJA1145A is in Standby mode when the event occurs, pin RXD is forced LOW to flag an interrupt/wake-up event. The detection of any enabled wake-up or interrupt event will trigger a wake-up in Standby mode. The detection of any enabled wake-up or interrupt event other than a SPIF interrupt will trigger a wake-up in Sleep mode.

The microcontroller can monitor events via the event status registers. An extra status register, the Global event status register (<u>Table 17</u>), is provided to help speed up software polling routines. By polling the Global event status register, the microcontroller can quickly determine the type of event captured (system, transceiver or WAKE) and then query the relevant table (Table 18, Table 19 or Table 20 respectively).

After the event source has been identified, the status flag should be cleared (set to 0) by writing 1 to the relevant bit (writing 0 will have no effect). A number of status bits can be cleared in a single write operation by writing 1 to all relevant bits.

It is strongly recommended to clear only the status bits that were set to 1 when the status registers were last read. This precaution ensures that events triggered just before the write access are not lost.

### 7.6.1 Interrupt/wake-up delay

If interrupt or wake-up events occur very frequently while the transceiver is in CAN Offline mode, they can have a significant impact on the software processing time (because pin RXD is repeatedly driven LOW, requiring a response from the microcontroller each time an interrupt/wake-up is generated). The TJA1145A incorporates an interrupt/wake-up delay timer to limit the disturbance to the software.

When one of the event capture status bits is cleared, pin RXD is released (HIGH) and a timer is started. If further events occur while the timer is running, the relevant status bits are set. If one or more events are pending when the timer expires after  $t_{d(event)}$ , pin RXD goes LOW again to alert the microcontroller.

In this way, the microcontroller is interrupted once to process a number of events rather than several times to process individual events. If all active event capture bits have been cleared (by the microcontroller) when the timer expires after  $t_{d(event)}$ , pin RXD remains HIGH (since there are no pending events). The event capture registers can be read at any time.

### 7.6.2 Sleep mode protection

It is very important that event detection is configured correctly when the TJA1145A switches to Sleep mode to ensure it will respond to a wake-up event. For this reason, and to avoid potential system deadlocks, at least one regular wake-up event must be enabled and all event status bits must be cleared before the TJA1145A switches to Sleep mode. Otherwise the TJA1145A will switch to Standby mode in response to a go-to-sleep command (MC = 001).

### 7.6.3 Event status and event capture registers

After an event source has been identified, the status flag should be cleared (set to 0) by writing 1 to the relevant status bit (writing 0 will have no effect).

Bit	Symbol	Access	Value	Description
7:4	reserved	R	-	
3	WPE	R		WAKE pin event:
			0	no pending WAKE pin event
			1	WAKE pin event pending at address 0x64
2	TRXE	R		transceiver event:
			0	no pending transceiver event
			1	transceiver event pending at address 0x63
1	reserved	R	-	
0	SYSE	R		system event:
			0	no pending system event
			1	system event pending at address 0x61

 Table 17.
 Global event status register (address 60h)

Bit	Symbol	Access	Value	Description
7:5	reserved	R	-	
4	PO <sup>[1]</sup>	R/W		power-on:
			0	no recent battery power-on
			1	the TJA1145A has left Off mode after battery power-on
3	reserved	R	-	
2	OTW	R/W		overtemperature warning:
			0	overtemperature not detected
			1	the global chip temperature has exceeded the overtemperature warning threshold (T <sub>th(warn)otp</sub> )
1	SPIF	R/W		SPI failure:
			0	no SPI failure detected
			1	SPI failure detected
0	reserved	R	-	

#### Table 18. System event status register (address 61h)

[1] PO is cleared when the TJA1145A is forced to Sleep mode due to an undervoltage event. The information stored in PO could be lost if the transition to Sleep mode was forced by an undervoltage event. Bit NMS, which is set to 0 when the TJA1145A switches to Normal mode after power-on, compensates for this.

Bit	Symbol	Access	Value	Description
7:6	reserved	R	-	
5	PNFDE	R/W		partial networking frame detection error:
			0	no partial networking frame detection error detected
			1	partial networking frame detection error detected
4 CBS	CBS	R/W		CAN-bus status:
			0	CAN-bus active
			1	no activity on CAN-bus for t <sub>to(silence)</sub>
3:2	reserved	R	-	
1	CF[1]	R/W		CAN failure:
			0	no CAN failure detected
			1	CAN failure event detected
0	CW	R/W		CAN wake-up:
			0	no CAN wake-up event detected
			1	CAN wake-up event detected

#### Table 19. Transceiver event status register (address 63h)

[1] CF is only enabled in Normal mode while the transceiver is in CAN Active mode and is triggered if TXD is clamped dominant OR a V<sub>CC</sub> undervoltage is detected (when CMC = 01).

Bit	Symbol	Access	Value	Description
7:2	reserved	R	-	
1 WPR	WPR	R/W		WAKE pin rising edge:
			0	no rising edge detected on WAKE pin
			1	rising edge detected on WAKE pin
0	WPF	R/W		WAKE pin falling edge:
			0	no falling edge detected on WAKE pin
			1	falling edge detected on WAKE pin

### Table 20. WAKE pin event status register (address 64h)

### Table 21. System event capture enable register (address 04h)

Bit	Symbol	Access	Value	Description
7:3	reserved	R	-	
2	2 OTWE	R/W		overtemperature warning enable:
			0	overtemperature warning disabled
			1	overtemperature warning enabled
1	1 SPIFE	R/W		SPI failure enable:
			0	SPI failure detection disabled
		1	SPI failure detection enabled	
0	reserved	R	-	

### Table 22. Transceiver event capture enable register (address 23h)

Bit	Symbol	Access	Value	Description
7:5	reserved	R	-	
4 (	CBSE	R/W		CAN-bus silence enable:
			0	CAN-bus silence detection disabled
			1	CAN-bus silence detection enabled
3:2	reserved	R	-	
1	CFE	R/W		CAN failure enable:
			0	CAN failure detection disabled
			1	CAN failure detection enabled
0	CWE	R/W		CAN wake-up enable:
			0	CAN wake-up detection disabled
			1	CAN wake-up detection enabled

#### Table 23. WAKE pin event capture enable register (address 4Ch)

Bit	Symbol	Access	Value	Description
7:2	reserved	R	-	
1	WPRE	R/W		WAKE pin rising-edge enable:
			0	rising-edge detection on WAKE pin disabled
			1	rising-edge detection on WAKE pin enabled

Bit	Symbol	Access	Value	Description
0	WPFE	R/W		WAKE pin falling-edge enable:
			0	falling-edge detection on WAKE pin disabled
			1	falling-edge detection on WAKE pin enabled

#### Table 23. WAKE pin event capture enable register (address 4Ch) ...continued

### 7.7 Device ID

A byte is reserved at address 0x7E for a TJA1145A identification code.

#### Table 24. Identification register (address 7Eh)

Bit	Symbol	Access	Value	Description
7:0	IDS[7:0]	R		device identification code
			70h	TJA1145AT, TJA1145ATK
			74h	TJA1145AT/FD, TJA1145ATK/FD

### 7.8 Lock control register

Sections of the register address area can be write-protected to protect against unintended modifications. Note that this facility only protects locked bits from being modified via the SPI and will not prevent the TJA1145A updating status registers etc.

Bit	Symbol	Access	Value	Description
7	reserved	R	-	cleared for future use
6	LK6C	R/W		lock control 6: address area 0x68 to 0x6F - partial networking data byte registers
			0	SPI write-access enabled
			1	SPI write-access disabled
5	LK5C	R/W		lock control 5: address area 0x50 to 0x5F
			0	SPI write-access enabled
			1	SPI write-access disabled
4	LK4C	R/W		lock control 4: address area 0x40 to 0x4F - WAKE pin configuration
			0	SPI write-access enabled
			1	SPI write-access disabled
3	LK3C	R/W		lock control 3: address area 0x30 to 0x3F
			0	SPI write-access enabled
			1	SPI write-access disabled
2	LK2C	R/W		lock control 2: address area 0x20 to 0x2F - transceiver control and partial networking
			0	SPI write-access enabled
			1	SPI write-access disabled
1	LK1C	R/W		lock control 1: address area 0x10 to 0x1F
			0	SPI write-access enabled
			1	SPI write-access disabled

Table 25.	Lock control	register	(address 0Ah)
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Bit	Symbol	Access	Value	Description
0	LK0C	R/W		lock control 0: address area 0x06 to 0x09 - general purpose memory
			0	SPI write-access enabled
			1	SPI write-access disabled

#### Table 25. Lock control register (address 0Ah) ...continued

### 7.9 General-purpose memory

TJA1145A allocates 4 bytes of memory for general-purpose registers used to store user information. The general purpose registers can be accessed via the SPI at address 0x06 to 0x09 (see <u>Table 26</u>).

### 7.10 VIO supply pin

Pin VIO should be connected to the microcontroller supply voltage. This will cause the signal levels of the TXD, RXD and the SPI interface pins to be adjusted to the I/O levels of the microcontroller, enabling direct interfacing without the need for glue logic.

### 7.11 V<sub>CC</sub>/V<sub>IO</sub> undervoltage protection

If an undervoltage is detected on pins VCC or VIO, and it remains valid for longer than the undervoltage detection delay time,  $t_{d(uvd)}$ , the TJA1145A is forced to Sleep mode (see Figure 4). A number of preventative measures are taken when the TJA1145A is forced to Sleep mode to avoid deadlock and unpredictable states:

- All previously captured events (address range 0x61 to 0x64) are cleared before the TJA1145A switches to Sleep Mode to avoid repeated attempts to wake up while an undervoltage is present.
- Both CAN wake-up (CWE = 1) and local wake-up via the WAKE pin (WPFE = WPRE = 1) are enabled in order to avoid a deadlock situation where the TJA1145A cannot be woken up after entering Sleep mode.
- Partial Networking is disabled (CPNC = 0) to ensure immediate wake-up in response to bus traffic after the TJA1145A has recovered from an undervoltage event.
- The Partial Networking Configuration bit is cleared (CPNOK = 0) to indicate that partial networking might not have been configured correctly when the TJA1145A switched to Sleep mode.

Status bit FSMS is set to 1 when a transition to Sleep mode is forced by an undervoltage event (see <u>Table 6</u>). This bit can be sampled after the TJA1145A wakes up from Sleep mode to allow the settings of CWE, WPFE, WPRE and CPNC to be re-adjusted if an undervoltage event forced the transition to Sleep mode (FSMS = 1).

### 7.12 SPI

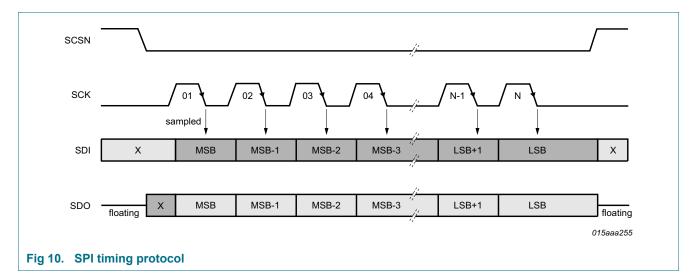
### 7.12.1 Introduction

The Serial Peripheral Interface (SPI) provides the communication link with the microcontroller, supporting multi-slave operations. The SPI is configured for full duplex data transfer, so status information is returned when new control data is shifted in. The interface also offers a read-only access option, allowing registers to be read back by the application without changing the register content.

The SPI uses four interface signals for synchronization and data transfer:

- SCSN: SPI chip select; active LOW; default level is HIGH (pull-up)
- SCK: SPI clock; default level is LOW due to internal pull-down
- SDI: SPI data input
- SDO: SPI data output; floating when pin SCSN is HIGH (may need external pull-up or pull-down if not available in the host controller)

Bit sampling is performed on the falling edge of the clock and data is shifted in/out on the rising edge, as illustrated in Figure 10.

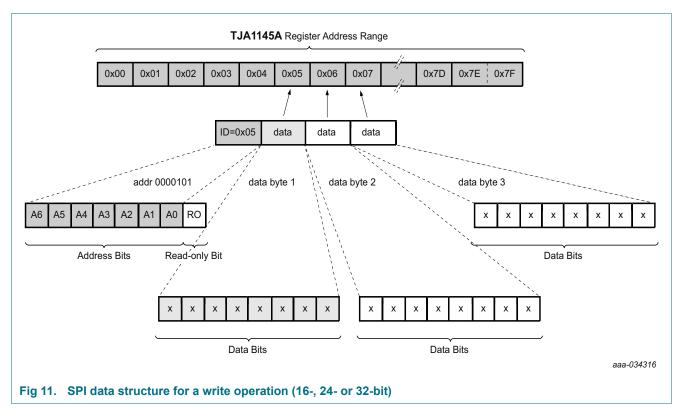


The SPI data in the TJA1145A is stored in a number of dedicated 8-bit registers. Each register is assigned a unique 7-bit address. Two bytes (16 bits) must be transmitted to the TJA1145A for a single register read or write operation. The first byte contains the 7-bit address along with a 'read-only' bit (the LSB). The read-only bit must be 0 to indicate a write operation (if this bit is 1, a read operation is assumed and any data on the SDI pin is ignored). The second byte contains the data to be written to the register.

24- and 32-bit read and write operations are also supported. The register address is automatically incremented, once for a 24-bit operation and twice for a 32-bit operation, as illustrated in Figure 11.

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During an SPI data read or write operation, the contents of the addressed register(s) is returned via pin SDO.

The TJA1145A tolerates attempts to write to registers that don't exist. If the available address space is exceeded during a write operation, the data above the valid address range is ignored (without generating an SPI failure event).

During a write operation, the TJA1145A monitors the number of SPI bits transmitted. If the number recorded is not 16, 24 or 32, then the write operation is aborted and an SPI failure event is captured (SPIF = 1).

If more than 32 bits are clocked in on pin SDI during a read operation, the data stream on SDI is reflected on SDO from bit 33 onwards.

### 7.12.2 Register map

The addressable register space contains 128 registers with addresses from 0x00 to 0x7F. An overview of the register mapping is provided in <u>Table 26</u> to <u>Table 30</u>. The functionality of the individual bits is discussed in more detail in relevant sections of the data sheet.

Address	Register Name	Bit:	Bit:								
		7	6	5	4	3	2	1	0		
0x01	Mode control	reserved MC									
0x03	Main status	FSMS	OTWS	NMS	reserved	d					
0x04	System event enable	reserved	reserved OTWE SPIFE								
0x06	Memory 0	GPM[7:0	]								

 Table 26.
 Overview of primary control registers

Address	Register Name	Bit:	Bit:								
		7	6	5	4	3	2	1	0		
0x07	Memory 1	GPM[1	GPM[15:8]								
0x08	Memory 2	GPM[2	3:16]								
0x09	Memory 3	GPM[3	GPM[31:24]								
0x0A	Lock control	reserve	reserved LK6C LK5C LK4C LK3C LK2C LK1C LK0C								

#### Table 26. Overview of primary control registers

### Table 27. Overview of transceiver control and partial networking registers

Address	Register Name	Bit:	Bit:									
		7	6	5	4	3	2	1	0			
0x20	CAN control	reserved	CFDC	PNCOK	CPNC	reserved		CMC				
0x22	Transceiver status	CTS	CPNERR	CPNS	COSCS	CBSS	reserved	VCS	CFS			
0x23	Transceiver event enable	reserved			CBSE	reserved		CFE	CWE			
0x26	Data rate	reserved					CDR					
0x27	Identifier 0	ID[7:0]										
0x28	Identifier 1	ID[15:8]										
0x29	Identifier 2	ID[23:16]										
0x2A	Identifier 3	reserved			ID[28:24]							
0x2B	Mask 0	M[7:0]										
0x2C	Mask 1	M[15:8]										
0x2D	Mask 2	M[23:16]										
0x2E	Mask 3	reserved			M[28:24]							
0x2F	Frame control	IDE	PNDM	reserved		DLC						
0x68	Data mask 0	DM0[7:0]										
0x69	Data mask 1	DM1[7:0]										
0x6A	Data mask 2	DM2[7:0]										
0x6B	Data mask 3	DM3[7:0]										
0x6C	Data mask 4	DM4[7:0]										
0x6D	Data mask 5	DM5[7:0]										
0x6E	Data mask 6	DM6[7:0]										
0x6F	Data mask 7	DM7[7:0]										

#### Table 28. Overview of WAKE pin control and status registers

Address	Register Name	Bit:									
		7	6	5	4	3	2	1	0		
0x4B	WAKE pin status	reserved		WPVS	reserved						
0x4C	WAKE pin enable	reserved						WPRE	WPFE		

Address	Register Name	Bit:	Bit:									
		7	6	5	4	3	2	1	0			
0x60	Event capture status	reserved				WPE	TRXE	reserved	SYSE			
0x61	System event status	reserved			PO	reserved	OTW	SPIF	reserved			
0x63	Transceiver event status	reserved		PNFDE	CBS	reserved		CF	CW			
0x64	WAKE pin event status	reserved						WPR	WPF			

### Table 29. Overview of Event Capture registers

### Table 30. Overview of Identification register

Address	Register Name	Bit:	Bit:								
		7	6	5	4	3	2	1	0		
0x7E	Identification	IDS[7:0]									

### 7.12.3 Register configuration in TJA1145A operating modes

A number of register bits may change state automatically when the TJA1145A switches from one operating mode to another. This is particularly evident when the TJA1145A switches to Off mode or when an undervoltage event forces a transition to Sleep mode. These changes are summarized in <u>Table 31</u>. If an SPI transmission is in progress when the TJA1145A changes state, the transmission is ignored (automatic state changes have priority).

Symbol	Off (reset values)	Standby	Normal	Sleep	Overtemp	Forced Sleep (uv)	
CBS	0	no change	no change	no change	no change	0	
CBSE	0	no change					
CBSS	1	actual state					
CDR	101	no change					
CF	0	no change	no change	no change	no change	0	
CFDC	0	no change					
CFE	0	no change					
CFS	0	actual state					
CMC	01	no change					
COSCS	0	actual state					
CPNC	0	no change	no change	no change	no change	0	
CPNERR	1	actual state					
CPNS	0	actual state					
CTS	0	0	actual state	0	0	0	
CW	0	no change	no change	no change	no change	0	
CWE	0	no change	no change	no change	no change	1	
DMn	1111111	no change					
DLC	0000	no change					
FSMS	0	no change	no change	0	no change	1	
GPMn	0000000	no change					
IDn	0000000	no change					
IDE	0	no change					
IDS	01110000 (AT, ATK) 01110100 (AT/FD, ATK/FD)	no change					
LKnC	0	no change					
Mn	0000000	no change					
MC	100	100	111	001	don't care	001	
NMS	1	no change	0	no change	no change	no change	
OTW	0	no change	no change	no change	no change	0	
OTWE	0	no change					
OTWS	0	actual state					
PNCOK	0	no change	no change	no change	no change	0	
PNDM	1	no change					
PNFDE	0	no change	no change	no change	no change	0	

Table 31.	Register bit	settings in	<b>TJA1145A</b>	operating modes

TJA1145A

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Symbol	Off (reset values)	Standby	Normal	Sleep	Overtemp	Forced Sleep (uv)
PO	1	no change	no change	no change	no change	0
SPIF	0	no change	no change	no change	no change	0
SPIFE	0	no change				
SYSE	1	no change	no change	no change	no change	0
TRXE	0	no change	no change	no change	no change	0
VCS	0	actual state				
WPE	0	no change	no change	no change	no change	0
WPF	0	no change	no change	no change	no change	0
WPFE	0	no change	no change	no change	no change	1
WPR	0	no change	no change	no change	no change	0
WPRE	0	no change	no change	no change	no change	1
WPVS	0	no change				

### Table 31. Register bit settings in TJA1145A operating modes ...continued

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# 8. Limiting values

#### Table 32. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	ol Parameter Conditions			Min	Max	Unit
V <sub>x</sub>	voltage on pin x <sup>[1]</sup>	pins VCC, VIO	[2]	-0.2	+6	V
		pins TXD, RXD, SDI, SDO, SCK, SCSN	[3]	-0.2	V <sub>IO</sub> + 0.2	V
		pins WAKE, INH		-18	+40	V
		pin BAT		-0.2	+40	V
		pins CANH and CANL with respect to any other pin		-58	+58	V
V <sub>(CANH-CANL)</sub>	voltage between pin CANH and pin CANL		-40	+40	V	
V <sub>trt</sub>	transient voltage	on pins CANL, CANH, WAKE, BAT	[4]			
		pulse 1		-100	-	V
		pulse 2a		-	75	V
		pulse 3a		-150	-	V
		pulse 3b		-	100	V
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2 (150 pF, 330 $\Omega$ ) discharge circuit	[5]			
		on pins CANH and CANL; pin BAT with capacitor; pin WAKE with 10 nF capacitor and 10 $k\Omega$ resistor		-6	+6	kV
		Human Body Model (HBM)				
		on any pin	[6]	-2	+2	kV
		on pins BAT, WAKE	[7]	-4	+4	kV
		on pins CANH, CANL	[8]	-8	+8	kV
		Machine Model (MM)	[9]			
		on any pin		-100	+100	V
		Charged Device Model (CDM)	[10]			
		on corner pins		-750	+750	V
		on any other pin		-500	+500	V
T <sub>vj</sub>	virtual junction temperature		[11]	-40	+150	°C
T <sub>stg</sub>	storage temperature			-55	+150	°C

[1] The device can sustain voltages up to the specified values over the product lifetime, provided applied voltages (including transients) never exceed these values.

[2] When the device is not powered up,  $I_{VCC(max)}$  = 25 mA.

[3] Maximum voltage should never exceed 6 V.

[4] Verified by an external test house according to IEC TS 62228, Section 4.2.4; parameters for standard pulses defined in ISO7637 part 2.

[5] Verified by an external test house according to IEC TS 62228, Section 4.3.

- [6] According to AEC-Q100-002.
- [7] Pins stressed to reference group containing all grounds, emulating the application circuit (Figure 15). HBM pulse as specified in AEC-Q100-002 used.
- [8] Pins stressed to reference group containing all ground and supply pins, emulating the application circuit (Figure 15). HBM pulse as specified in AEC-Q100-002 used.

[9] According to AEC-Q100-003.

[10] According to AEC-Q100-011.

[11] In accordance with IEC 60747-1. An alternative definition of virtual junction temperature is:  $T_{vj} = T_{amb} + P \times R_{th(j-a)}$ , where  $R_{th(j-a)}$  is a fixed value used in the calculation of  $T_{vj}$ . The rating for  $T_{vj}$  limits the allowable combinations of power dissipation (P) and ambient temperature ( $T_{amb}$ ).

# 9. Thermal characteristics

#### Table 33. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(vj-a)</sub>	thermal resistance from virtual junction to ambient	SO14 [1]	106	K/W
		HVSON14	60	K/W

 According to JEDEC JESD51-2, JESD51-5 and JESD51-7 at natural convection on 2s2p board. Board with two inner copper layers (thickness: 35 μm) and thermal via array under the exposed pad connected to the first inner copper layer (thickness: 70 μm).

# **10. Static characteristics**

#### Table 34. Static characteristics

 $T_{vj} = -40 \ \text{C}$  to +150  $\ \text{C}$ ;  $V_{BAT} = 4.5 \text{ V}$  to 28 V;  $V_{IO} = 2.85 \text{ V}$  to 5.5 V;  $V_{CC} = 4.5 \text{ V}$  to 5.5 V;  $R_L = R_{(CANH-CANL)} = 60 \ \Omega$ ; all voltages are defined with respect to ground; positive currents flow into the IC; typical values are given at  $V_{BAT} = 13 \text{ V}$ ; unless otherwise specified[1].

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply; pi	n BAT					
V <sub>th(det)pon</sub>	power-on detection threshold voltage	V <sub>BAT</sub> rising	4.2	-	4.55	V
V <sub>th(det)poff</sub>	power-off detection threshold voltage	V <sub>BAT</sub> falling	2.8	-	3	V
V <sub>uvr(CAN)</sub>	CAN undervoltage recovery voltage	V <sub>BAT</sub> rising	4.5	-	5	V
V <sub>uvd(CAN)</sub>	CAN undervoltage detection voltage	V <sub>BAT</sub> falling	4.2	-	4.55	V
I <sub>BAT</sub>	battery supply current	Normal mode; MC = 111	-	1	1.5	mA
		Sleep mode; MC = 001; CWE = 1; CAN Offline mode; $-40 \degree C < T_{vj} < 85 \degree C;$ V <sub>BAT</sub> = 7 V to 18 V	-	48	64	μA
		Standby mode; MC = 100; CWE = 1; CAN Offline mode; $-40 \text{ °C} < T_{vj} < 85 \text{ °C};$ $V_{BAT} = 7 \text{ V to } 18 \text{ V}$	-	56	73	μA
		additional current in CAN Offline Bias mode; –40 °C < T <sub>vj</sub> < 85 °C	-	46	63	μA
		additional current in CAN Offline Bias mode with active partial networking decoder; Standby or Sleep mode; -40 °C < T <sub>vj</sub> < 85 °C	2]	0.4	0.65	mA
		additional current from WAKE input; WPRE = WPFE = 1; -40 °C < T <sub>vj</sub> < 85 °C		2	3	μA

## Supply; pin VCC

V <sub>uvd(VCC)</sub>	undervoltage detection voltage on pin VCC		4.5	-	4.75	V
I <sub>CC</sub>	supply current	CAN Active mode; CAN recessive; V <sub>TXD</sub> = V <sub>IO</sub>	-	3	6	mA
		CAN Active mode; CAN dominant; V <sub>TXD</sub> = 0 V	-	45	65	mA
		Standby/Normal mode; CAN inactive; –40 °C < T <sub>vj</sub> < 85 °C	-	4.7	8.5	μA
		Sleep mode; CAN inactive; –40 °C < T <sub>vj</sub> < 85 °C	-	3.8	7	μA
		short circuit on bus lines; CAN dominant; V <sub>TXD</sub> = 0 V; –3 V < (V <sub>CANH</sub> = V <sub>CANL</sub> ) < +18 V	-	55	65	mA

#### Table 34. Static characteristics ...continued

 $T_{vj} = -40 \ ^{\circ}C$  to +150  $^{\circ}C$ ;  $V_{BAT} = 4.5 \ V$  to 28 V;  $V_{IO} = 2.85 \ V$  to 5.5 V;  $V_{CC} = 4.5 \ V$  to 5.5 V;  $R_L = R_{(CANH-CANL)} = 60 \ \Omega$ ; all voltages are defined with respect to ground; positive currents flow into the IC; typical values are given at  $V_{BAT} = 13 \ V$ ; unless otherwise specified<sup>[1]</sup>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply; pi	n VIO					
V <sub>uvd(VIO)</sub>	undervoltage detection voltage on pin VIO	V <sub>BAT</sub> > 4.5 V	2.7	-	2.85	V
I <sub>IO</sub>	supply current on pin V <sub>IO</sub>	Standby/Normal mode; –40 °C < T <sub>vj</sub> < 85 °C	-	7.1	11	μA
		Sleep mode; –40 °C < T <sub>vj</sub> < 85 °C	-	5	8	μA
Serial peri	pheral interface inputs; pins SDI, \$	SCK and SCSN				
V <sub>th(sw)</sub>	switching threshold voltage	V <sub>IO</sub> = 2.97 V to 5.5 V	0.25V <sub>IO</sub>	-	0.75V <sub>IO</sub>	V
V <sub>th(sw)hys</sub>	switching threshold voltage hysteresis	V <sub>IO</sub> = 2.97 V to 5.5 V	0.05V <sub>IO</sub>	-	-	V
R <sub>pd(SCK)</sub>	pull-down resistance on pin SCK		40	60	80	kΩ
R <sub>pu(SCSN)</sub>	pull-up resistance on pin SCSN		40	60	80	kΩ
R <sub>pd(SDI)</sub>	pull-down resistance on pin SDI	V <sub>SDI</sub> < V <sub>th(sw)</sub>	40	60	80	kΩ
R <sub>pu(SDI)</sub>	pull-up resistance on pin SDI	$V_{SDI} > V_{th(sw)}$	40	60	80	kΩ
Serial peri	pheral interface data output; pin S	DO			÷	
V <sub>OH</sub>	HIGH-level output voltage	I <sub>OH</sub> = -4 mA	V <sub>IO</sub> – 0.4	-	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>OL</sub> = 4 mA	-	-	0.4	V
I <sub>LO(off)</sub>	off-state output leakage current	$V_{SCSN} = V_{IO}; V_O = 0 V \text{ to } V_{IO}$	-5	-	+5	μA
Inhibit out	put: pin INH					_
Vo	output voltage	I <sub>INH</sub> = -180 μA	V <sub>BAT</sub> – 0.8	-	V <sub>BAT</sub>	V
R <sub>pd</sub>	pull-down resistance	Sleep mode	3	4	5	MΩ
CAN trans	mit data input; pin TXD			1		
V <sub>th(sw)</sub>	switching threshold voltage	V <sub>IO</sub> = 2.97 V to 5.5 V	0.25V <sub>IO</sub>	-	0.75V <sub>IO</sub>	V
V <sub>th(sw)hys</sub>	switching threshold voltage hysteresis	V <sub>IO</sub> = 2.97 V to 5.5 V	0.05V <sub>IO</sub>	-	-	V
R <sub>pu</sub>	pull-up resistance		40	60	80	kΩ
CAN recei	ve data output; pin RXD					_
V <sub>OH</sub>	HIGH-level output voltage	I <sub>OH</sub> = -4 mA	V <sub>IO</sub> – 0.4	-	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>OL</sub> = 4 mA	-	-	0.4	V
R <sub>pu</sub>	pull-up resistance	CAN Offline mode	40	60	80	kΩ
Local wak	e input; pin WAKE					
V <sub>th(sw)</sub> r	rising switching threshold voltage		2.8	-	4.1	V
V <sub>th(sw)f</sub>	falling switching threshold voltage		2.4	-	3.75	V
V <sub>hys(i)</sub>	input hysteresis voltage		250	-	800	mV
li	input current	T <sub>vi</sub> = -40 °C to +85 °C	-	-	1.5	μA

#### Table 34. Static characteristics ...continued

 $T_{vj} = -40 \text{ }^{\circ}\text{C}$  to +150  $^{\circ}\text{C}$ ;  $V_{BAT} = 4.5 \text{ V}$  to 28 V;  $V_{IO} = 2.85 \text{ V}$  to 5.5 V;  $V_{CC} = 4.5 \text{ V}$  to 5.5 V;  $R_L = R_{(CANH-CANL)} = 60 \Omega$ ; all voltages are defined with respect to ground; positive currents flow into the IC; typical values are given at  $V_{BAT} = 13 \text{ V}$ ; unless otherwise specified<sup>[1]</sup>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
High-speed	CAN bus lines; pins CANH and	CANL				
V <sub>O(dom)</sub>	dominant output voltage	CAN Active mode; $V_{TXD} = 0 V$ ; t < $t_{to(dom)TXD}$				
		pin CANH; $R_L = 50 \Omega$ to $65 \Omega$	2.75	3.5	4.5	V
		pin CANL; $R_L = 50 \Omega$ to 65 $\Omega$	0.5	1.5	2.25	V
V <sub>dom(TX)</sub> sym	transmitter dominant voltage symmetry	$\label{eq:Vdom(TX)sym} \begin{array}{l} V_{dom(TX)sym} = V_{CC} - V_{CANH} - V_{CANL};\\ V_{CC} = 5 \ V \end{array}$	-400	-	+400	mV
V <sub>TXsym</sub>	transmitter voltage symmetry	$V_{TXsym} = V_{CANH} + V_{CANL};$ $f_{TXD} = 250 \text{ kHz}, 1 \text{ MHz or } 2.5 \text{ MHz};$ $V_{CC} = 4.75 \text{ V to } 5.25 \text{ V};$ $C_{SPLIT} = 4.7 \text{ nF}$	0.9V <sub>CC</sub>	-	1.1V <sub>CC</sub>	V
V <sub>O(dif)</sub>	differential output voltage	CAN Active mode (dominant); $V_{TXD} = 0 V$ ; $V_{CC} = 4.75 V$ to 5.5 V; $t < t_{to(dom)TXD}$				
		$R_L$ = 45 $\Omega$ to 70 $\Omega$	1.5	-	3	V
		R <sub>L</sub> = 2240 Ω	1.5	-	5	V
		recessive; R <sub>L</sub> = no load				
		CAN Active/Listen-only/Offline Bias mode; V <sub>TXD</sub> = V <sub>IO</sub>	-50	-	+50	mV
		CAN Offline mode	-0.2	-	+0.2	V
V <sub>O(rec)</sub>	recessive output voltage	CAN Active mode; $V_{TXD} = V_{IO}$ ; R <sub>L</sub> = no load	2	0.5V <sub>CC</sub>	3	V
		CAN Offline mode; R <sub>L</sub> = no load	-0.1	-	+0.1	V
		CAN Offline Bias/Listen-only modes; R <sub>L</sub> = no load; V <sub>CC</sub> = 0 V	2	2.5	3	V
I <sub>O(sc)dom</sub>	dominant short-circuit output current	CAN Active mode; $V_{TXD} = 0 V; V_{CC} = 5 V$				_
		pin CANH; V <sub>CANH</sub> = -15 V to +27 V	-55	-	-	mA
		pin CANL; V <sub>CANL</sub> = -15 V to +27 V	-	-	+55	mA
I <sub>O(sc)rec</sub>	recessive short-circuit output current	$V_{CANL} = V_{CANH} = -27 V \text{ to } +32 V;$ $V_{TXD} = V_{IO}$	-3	-	+3	mA
V <sub>th(RX)</sub> dif	differential receiver threshold voltage	$\label{eq:linear_constraint} \begin{array}{l} -12 \ V \leq V_{CANL} \leq +12 \ V; \\ -12 \ V \leq V_{CANH} \leq +12 \ V \end{array}$				
		CAN Active/Listen-only modes	0.5	0.7	0.9	V
		CAN Offline mode	0.4	0.7	1.15	V
V <sub>rec(RX)</sub>	receiver recessive voltage	$\label{eq:V_CANL} \begin{split} -12 \ V &\leq V_{CANL} \leq +12 \ V; \\ -12 \ V &\leq V_{CANH} \leq +12 \ V \end{split}$				
		CAN Active/Listen-only modes	-4[2]	-	0.5	V
		CAN Offline mode	-4[2]	-	0.4	V

#### Table 34. Static characteristics ... continued

 $T_{vj} = -40 \text{ °C to } +150 \text{ °C}; V_{BAT} = 4.5 \text{ V to } 28 \text{ V}; V_{IO} = 2.85 \text{ V to } 5.5 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; R_L = R_{(CANH-CANL)} = 60 \Omega;$  all voltages are defined with respect to ground; positive currents flow into the IC; typical values are given at  $V_{BAT} = 13 \text{ V};$  unless otherwise specified<sup>[1]</sup>.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>dom(RX)</sub>	receiver dominant voltage	$\begin{array}{l} -12 \ V \leq V_{CANL} \leq +12 \ V; \\ -12 \ V \leq V_{CANH} \leq +12 \ V \end{array}$					
		CAN Active/Listen-only modes		0.9	-	9.0 <mark>[2]</mark>	V
		CAN Offline mode		1.15	-	9.0 <mark>[2]</mark>	V
V <sub>hys(RX)</sub> dif	differential receiver hysteresis voltage	$\begin{array}{l} \mbox{CAN Active/Listen-only modes;} \\ -12 \ V \leq V_{CANL} \leq +12 \ V; \\ -12 \ V \leq V_{CANH} \leq +12 \ V \end{array}$		1	30	60	mV
R <sub>i</sub>	input resistance	$\begin{array}{l} -2 \ V \leq V_{CANL} \leq +7 \ V; \\ -2 \ V \leq V_{CANH} \leq +7 \ V \end{array}$		9	15	28	kΩ
$\Delta R_i$	input resistance deviation	$\begin{array}{l} 0 \ V \leq V_{CANL} \leq +5 \ V; \\ 0 \ V \leq V_{CANH} \leq +5 \ V \end{array}$		-1	-	+1	%
R <sub>i(dif)</sub>	differential input resistance	$\label{eq:V_CANL} \begin{array}{l} -2 \ V \leq V_{CANL} \leq +7 \ V; \\ -2 \ V \leq V_{CANH} \leq +7 \ V \end{array}$		19	30	52	kΩ
C <sub>i(cm)</sub>	common-mode input capacitance		[2]	-	-	20	pF
C <sub>i(dif)</sub>	differential input capacitance		[2]	-	-	10	pF
IL	leakage current	$V_{BAT} = V_{CC} = 0 V \text{ or } V_{BAT} = V_{CC} =$ shorted to ground via 47 k $\Omega$ ; $V_{CANH} = V_{CANL} = 5 V$		-5	-	+5	μA
Temperatu	re protection	1			<b>I</b>		
T <sub>th(act)otp</sub>	overtemperature protection activation threshold temperature			167	177	187	°C
T <sub>th(rel)otp</sub>	overtemperature protection release threshold temperature			127	137	147	°C
T <sub>th(warn)otp</sub>	overtemperature protection warning threshold temperature			127	137	147	°C

[1] All parameters are guaranteed over the virtual junction temperature range by design. Factory testing uses correlated test conditions to cover the specified temperature and power supply voltage range.

[2] Not tested in production; guaranteed by design.

[3] The test circuit used to measure the bus output voltage symmetry (which includes C<sub>SPLIT</sub>) is shown in Figure 17.

# **11. Dynamic characteristics**

#### Table 35. Dynamic characteristics

 $T_{vj} = -40 \ \text{C}$  to +150  $\ \text{C}$ ;  $V_{BAT} = 4.5 \text{ V}$  to 28 V;  $V_{IO} = 2.85 \text{ V}$  to 5.5 V;  $V_{CC} = 4.5 \text{ V}$  to 5.5 V;  $R_L = R_{(CANH-CANL)} = 60 \ \Omega$ ; all voltages are defined with respect to ground; positive currents flow into the IC; typical values are given at  $V_{BAT} = 13 \text{ V}$ ; unless otherwise specified.<sup>[1]</sup>

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Voltage sourc	es; pins BAT, VCC and VIO					
t <sub>startup</sub>	start-up time	from V <sub>BAT</sub> exceeding the power-on detection threshold until INH active	-	2.8	4.7	ms
t <sub>d(uvd)</sub>	undervoltage detection delay time		6	-	54	μs
t <sub>d(uvd-sleep)</sub>	delay time from undervoltage detection to sleep mode	from undervoltage detection on VCC and/or VIO until TJA1145A forced to Sleep mode	180	-	440	ms
Serial periphe	ral interface timing; pins SCSN, SCK	, SDI and SDO; see <u>Figure 14</u>		·		
t <sub>cy(clk)</sub>	clock cycle time	Normal/Standby modes	250	-	-	ns
		Sleep mode	1	-	-	μs
t <sub>SPILEAD</sub>	SPI enable lead time	Normal/Standby modes	50	-	-	ns
		Sleep mode	200	-	-	ns
t <sub>SPILAG</sub>	SPI enable lag time	Normal/Standby modes	50	-	-	ns
		Sleep mode	200	-	-	ns
t <sub>clk(H)</sub>	clock HIGH time	Normal/Standby modes	100	-	-	ns
	Sleep mode		475	-	-	ns
t <sub>clk(L)</sub>	clock LOW time	Normal/Standby modes	100	-	-	ns
		Sleep mode	475	-	-	ns
t <sub>su(D)</sub>	data input set-up time	Normal/Standby modes	50	-	-	ns
		Sleep mode	200	-	-	ns
t <sub>h(D)</sub>	data input hold time	Normal/Standby modes	50	-	-	ns
		Sleep mode	200	-	-	ns
t <sub>v(Q)</sub>	data output valid time	pin SDO; C <sub>L</sub> = 20 pF; Normal/Standby modes	-	-	50	ns
		pin SDO; C <sub>L</sub> = 20 pF; Sleep mode	-	-	200	ns
t <sub>d(SDI-SDO)</sub>	SDI to SDO delay time	SPI address bits and read-only bit; $C_L = 20 \text{ pF}$	-	-	50	ns
t <sub>WH(S)</sub>	chip select pulse width HIGH	pin SCSN; Normal/Standby modes	250	-	-	ns
		pin SCSN; Sleep mode	1	-	-	μs
$t_{d(SCKL-SCSNL)}$	delay time from SCK LOW to SCSN LOW		50	-	-	ns
CAN transceiv	/er timing; pins CANH, CANL, TXD ar	d RXD				
	delay time from TXD to bus dominant	[2]	_	80	_	ns
t <sub>d(TXD-busdom)</sub> t <sub>d(TXD-busrec)</sub>	delay time from TXD to bus recessive	[2]	-	80	-	ns
t <sub>d(busdom-RXD)</sub>	delay time from bus dominant to RXD	[2]	-	105	-	ns

### Table 35. Dynamic characteristics ...continued

 $T_{vj} = -40 \ ^{\circ}C$  to +150  $^{\circ}C$ ;  $V_{BAT} = 4.5 \ V$  to 28 V;  $V_{IO} = 2.85 \ V$  to 5.5 V;  $V_{CC} = 4.5 \ V$  to 5.5 V;  $R_L = R_{(CANH-CANL)} = 60 \ \Omega$ ; all voltages are defined with respect to ground; positive currents flow into the IC; typical values are given at  $V_{BAT} = 13 \ V$ ; unless otherwise specified.<sup>[1]</sup>

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
t <sub>d(busrec-RXD)</sub>	delay time from bus recessive to RXD	]	[2]	-	120	-	ns
t <sub>d(TXDL-RXDL)</sub>	delay time from TXD LOW to RXD LOW	t <sub>bit(TXD)</sub> = 200 ns	<u>[3]</u>	-	-	255	ns
t <sub>d(TXDH-RXDH)</sub>	delay time from TXD HIGH to RXD HIGH	t <sub>bit(TXD)</sub> = 200 ns	<u>[3]</u>	-	-	255	ns
t <sub>bit(bus)</sub>	transmitted recessive bit width	t <sub>bit(TXD)</sub> = 500 ns	[3]	435	-	530	ns
		t <sub>bit(TXD)</sub> = 200 ns	[3]	155	-	210	ns
t <sub>bit(RXD)</sub>	bit time on pin RXD	t <sub>bit(TXD)</sub> = 500 ns	[3]	400	-	550	ns
		t <sub>bit(TXD)</sub> = 200 ns	[3]	120	-	220	ns
$\Delta t_{rec}$	receiver timing symmetry	t <sub>bit(TXD)</sub> = 500 ns		-65	-	+40	ns
		t <sub>bit(TXD)</sub> = 200 ns		-45	-	+15	ns
t <sub>wake(busdom)</sub>	bus dominant wake-up time	first pulse (after first recessive) for wake-up on pins CANH and CANL; CAN Offline mode		0.5	-	1.8	μs
		second pulse for wake-up on pins CANH and CANL		0.5	-	1.8	μS
t <sub>wake(busrec)</sub>	bus recessive wake-up time	first pulse for wake-up on pins CANH and CANL; CAN Offline mode		0.5	-	1.8	μs
		second pulse (after first dominant) for wake-up on pins CANH and CANL		0.5	-	1.8	μs
t <sub>to(wake)bus</sub>	bus wake-up time-out time	between first and second dominant pulses; CAN Offline mode		0.8	-	10	ms
t <sub>to(dom)TXD</sub>	TXD dominant time-out time	CAN Active mode; V <sub>TXD</sub> = 0 V		2.7	-	3.3	ms
t <sub>to(silence)</sub>	bus silence time-out time	recessive time measurement started in all CAN modes		0.95	-	1.17	s
t <sub>d(busact-bias)</sub>	delay time from bus active to bias			-	-	200	μs
t <sub>startup(CAN)</sub>	CAN start-up time	when switching to Active mode (CTS = 1)		-	-	220	μS
CAN partial n	etworking						1
N <sub>bit(idle)</sub>	number of idle bits	before a new SOF is accepted; CFDC = 1	<u>[4]</u>	6	-	10	-
t <sub>fltr(bit)dom</sub>	dominant bit filter time		[4] [5]	5	-	17.5	%
Pin RXD: inte	rrupt/wake-up event timing (valid in	CAN Offline mode only)					
t <sub>d(event)</sub>	event capture delay time	CAN Offline mode		0.9	-	1.1	ms
t <sub>blank</sub>	blanking time	when switching from Offline to Active/Listen-only mode		-	-	25	μs

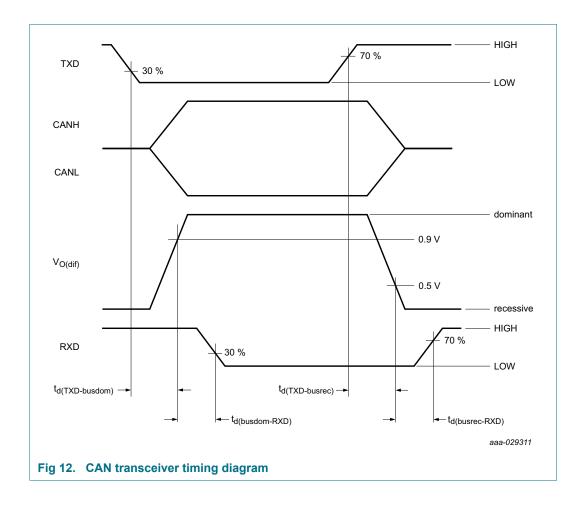
#### Table 35. Dynamic characteristics ...continued

 $T_{vj} = -40 \text{ °C to } +150 \text{ °C}; V_{BAT} = 4.5 \text{ V to } 28 \text{ V}; V_{IO} = 2.85 \text{ V to } 5.5 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; R_L = R_{(CANH-CANL)} = 60 \Omega;$  all voltages are defined with respect to ground; positive currents flow into the IC; typical values are given at  $V_{BAT} = 13 \text{ V};$  unless otherwise specified.<sup>[1]</sup>

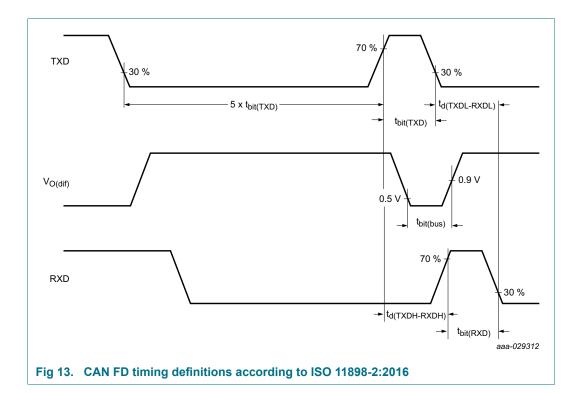
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Pin WAKE	·					
t <sub>wake</sub>	wake-up time		50	-	-	μs
Pin INH						
t <sub>d(buswake-INHH)</sub>	delay time from bus wake-up to INH HIGH		-	-	100	μs

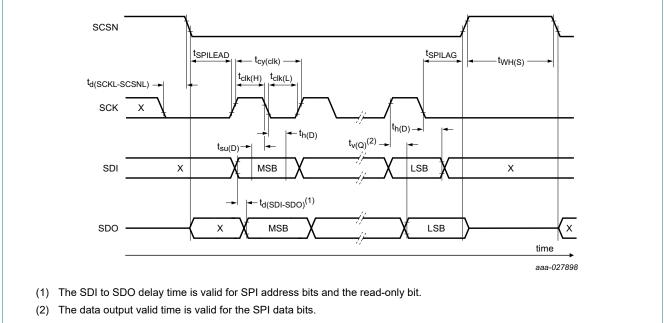
[1] All parameters are guaranteed over the virtual junction temperature range by design. Factory testing uses correlated test conditions to cover the specified temperature and power supply voltage range.

- [2] See Figure 12 and Figure 16.
- [3] See Figure 13 and Figure 16.
- [4] Not tested in production; guaranteed by design.
- [5] Up to 2 Mbit/s data speed.



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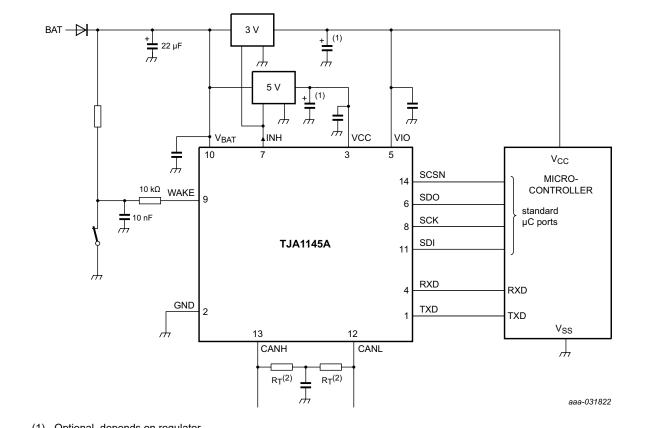




## Fig 14. SPI timing diagram

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# 12. Application information



# 12.1 Application diagram

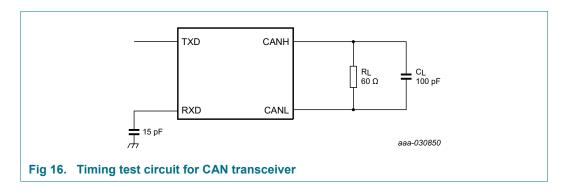
- (1) Optional, depends on regulator.
- (2) For bus line end nodes,  $R_T = 60 \Omega$  in order to support the 'split termination concept'. For sub-nodes, an optional 'weak' termination of e.g.  $R_T = 1.3 k\Omega$  can be used, if required by the OEM.

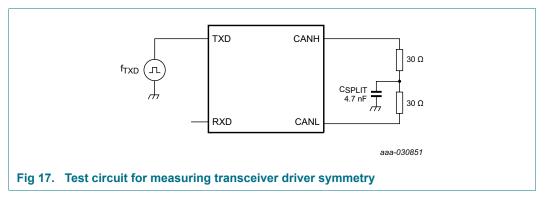
#### Fig 15. Typical application using the TJA1145A

# **12.2 Application hints**

Further information on the application of the TJA1145A can be found in the NXP application hints document *AH1903 Application Hints - High speed CAN transceiver for partial networking TJA1145A.* 

# **13. Test information**

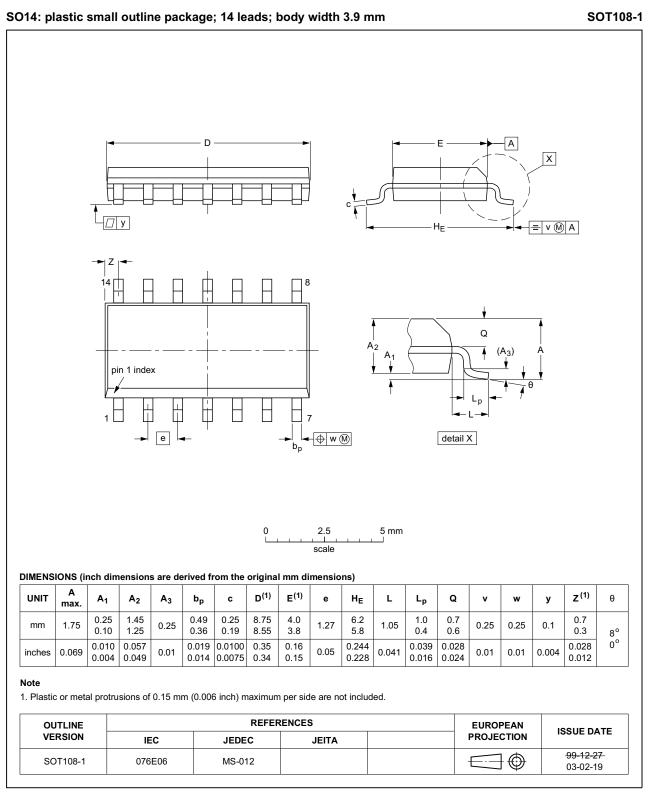




# **13.1 Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q100 Rev-G - Failure mechanism based stress test qualification for integrated circuits*, and is suitable for use in automotive applications.

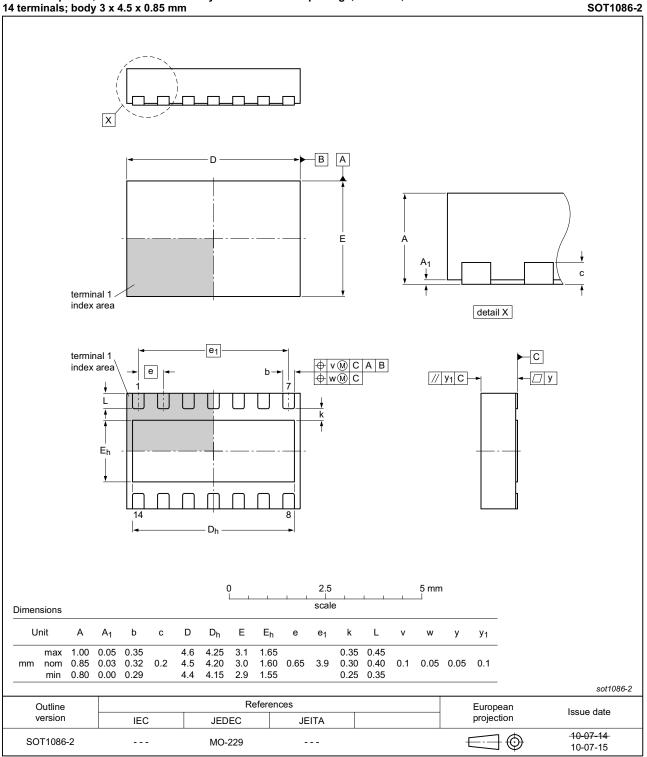
# 14. Package outline



## Fig 18. Package outline SOT108-1 (SO14)

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#### HVSON14: plastic, thermal enhanced very thin small outline package; no leads; 14 terminals; body 3 x 4.5 x 0.85 mm

#### Fig 19. Package outline SOT1086-2 (HVSON14)

# **15. Handling information**

All input and output pins are protected against ElectroStatic Discharge (ESD) under normal handling. When handling ensure that the appropriate precautions are taken as described in *JESD625-A* or equivalent standards.

# 16. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

## 16.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

## 16.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- · Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- · The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

# 16.3 Wave soldering

Key characteristics in wave soldering are:

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- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

## 16.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 20</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with <u>Table 36</u> and <u>37</u>

#### Table 36. SnPb eutectic process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)					
	Volume (mm <sup>3</sup> )					
	< 350	≥ 350				
< 2.5	235	220				
≥ 2.5	220	220				

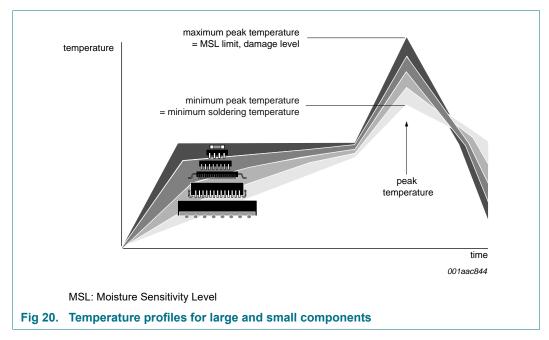
#### Table 37. Lead-free process (from J-STD-020D)

Package thickness (mm)	Package reflow	Package reflow temperature (°C)					
	Volume (mm <sup>3</sup> )	Volume (mm <sup>3</sup> )					
	< 350	> 2000					
< 1.6	260	260	260				
1.6 to 2.5	260	245					
> 2.5	250 245 245						

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see <u>Figure 20</u>.

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For further information on temperature profiles, refer to Application Note *AN10365 "Surface mount reflow soldering description"*.

# 17. Soldering of HVSON packages

<u>Section 16</u> contains a brief introduction to the techniques most commonly used to solder Surface Mounted Devices (SMD). A more detailed discussion on soldering HVSON leadless package ICs can found in the following application notes:

- AN10365 'Surface mount reflow soldering description"
- AN10366 "HVQFN application information"

# 18. Appendix: ISO 11898-2:2016 parameter cross-reference list

### Table 38. ISO 11898-2:2016 to NXP data sheet parameter conversion

SO 11898-2:2016	NXP data sheet			
Parameter	Notation	Symbol	Parameter	
IS-PMA dominant output characteristics		L		
Single ended voltage on CAN_H	V <sub>CAN_H</sub>	V <sub>O(dom)</sub>	dominant output voltage	
Single ended voltage on CAN_L	V <sub>CAN_L</sub>			
Differential voltage on normal bus load	V <sub>Diff</sub>	V <sub>O(dif)</sub>	differential output voltage	
Differential voltage on effective resistance during arbitration				
Optional: Differential voltage on extended bus load range				
IS-PMA driver symmetry				
Driver symmetry	V <sub>SYM</sub>	V <sub>TXsym</sub>	transmitter voltage symmetry	
Aximum HS-PMA driver output current		I.		
Absolute current on CAN_H	I <sub>CAN_H</sub>	I <sub>O(sc)dom</sub>	dominant short-circuit output	
Absolute current on CAN_L	I <sub>CAN_L</sub>		current	
IS-PMA recessive output characteristics, bus biasing	active/inacti	ve		
Single ended output voltage on CAN_H	V <sub>CAN_H</sub>	V <sub>O(rec)</sub>	recessive output voltage	
Single ended output voltage on CAN_L	V <sub>CAN_L</sub>			
Differential output voltage	V <sub>Diff</sub>	V <sub>O(dif)</sub>	differential output voltage	
Optional HS-PMA transmit dominant timeout				
Fransmit dominant timeout, long	t <sub>dom</sub>	t <sub>to(dom)TXD</sub>	TXD dominant time-out time	
Fransmit dominant timeout, short	_			
IS-PMA static receiver input characteristics, bus bias	sing active/in	active		
Recessive state differential input voltage range Dominant state differential input voltage range	V <sub>Diff</sub>	V <sub>th(RX)dif</sub>	differential receiver threshold voltage	
		V <sub>rec(RX)</sub>	receiver recessive voltage	
		V <sub>dom(RX)</sub>	receiver dominant voltage	
IS-PMA receiver input resistance (matching)				
	R <sub>Diff</sub>	R <sub>i(dif)</sub>	differential input resistance	
<b>HS-PMA receiver input resistance (matching)</b> Differential internal resistance Single ended internal resistance	R <sub>Diff</sub> R <sub>CAN_H</sub> R <sub>CAN_L</sub>	R <sub>i(dif)</sub> R <sub>i</sub>	differential input resistance input resistance	
Differential internal resistance Single ended internal resistance	R <sub>CAN_H</sub>		· ·	
Differential internal resistance	R <sub>CAN_H</sub> R <sub>CAN_L</sub>	R <sub>i</sub>	input resistance	
Differential internal resistance Single ended internal resistance Matching of internal resistance	R <sub>CAN_H</sub> R <sub>CAN_L</sub>	R <sub>i</sub>	input resistance	
Differential internal resistance Single ended internal resistance Matching of internal resistance HS-PMA implementation loop delay requirement	R <sub>CAN_H</sub> R <sub>CAN_L</sub> MR	R <sub>i</sub> ΔR <sub>i</sub>	input resistance input resistance deviation delay time from TXD HIGH to	
Differential internal resistance Single ended internal resistance Matching of internal resistance <b>IS-PMA implementation loop delay requirement</b> Loop delay Dptional HS-PMA implementation data signal timing r	R <sub>CAN_H</sub> R <sub>CAN_L</sub> MR t <sub>Loop</sub>	$R_{i}$ $\Delta R_{i}$ $t_{d(TXDH-RXDH)}$ $t_{d(TXDL-RXDL)}$	input resistance input resistance deviation delay time from TXD HIGH to RXD HIGH delay time from TXD LOW to RXD LOW	
Differential internal resistance Single ended internal resistance Matching of internal resistance HS-PMA implementation loop delay requirement	R <sub>CAN_H</sub> R <sub>CAN_L</sub> MR t <sub>Loop</sub>	$R_{i}$ $\Delta R_{i}$ $t_{d(TXDH-RXDH)}$ $t_{d(TXDL-RXDL)}$	input resistance input resistance deviation delay time from TXD HIGH to RXD HIGH delay time from TXD LOW to RXD LOW	
Differential internal resistance Single ended internal resistance Matching of internal resistance HS-PMA implementation loop delay requirement coop delay Deptional HS-PMA implementation data signal timing r Mbit/s and above 2 Mbit/s up to 5 Mbit/s Transmitted recessive bit width @ 2 Mbit/s / @ 5 Mbit/s,	R <sub>CAN_H</sub> R <sub>CAN_L</sub> MR t <sub>Loop</sub>	R <sub>i</sub> ΔR <sub>i</sub> t <sub>d(TXDH-RXDH)</sub> t <sub>d(TXDL-RXDL)</sub> for use with bit	input resistance input resistance deviation delay time from TXD HIGH to RXD HIGH delay time from TXD LOW to RXD LOW rates above 1 Mbit/s up to	

#### Table 38. ISO 11898-2:2016 to NXP data sheet parameter conversion

ISO 11898-2:2016		NXP data she	et							
Parameter	Notation	Symbol	Parameter							
HS-PMA maximum ratings of V <sub>CAN_H</sub> , V <sub>CAN_L</sub> and V <sub>Diff</sub>										
Maximum rating V <sub>Diff</sub>	V <sub>Diff</sub>	V <sub>(CANH-CANL)</sub>	voltage between pin CANH and pin CANL							
General maximum rating $V_{CAN_H}$ and $V_{CAN_L}$	V <sub>CAN_H</sub>	V <sub>x</sub>	voltage on pin x							
Optional: Extended maximum rating VCAN_H and VCAN_L	V <sub>CAN_L</sub>									
HS-PMA maximum leakage currents on CAN_H and C/	HS-PMA maximum leakage currents on CAN_H and CAN_L, unpowered									
Leakage current on CAN_H, CAN_L	I <sub>CAN_H</sub> I <sub>CAN_L</sub>	۱ <sub>L</sub>	leakage current							
Number of recessive bits before next SOF										
Number of recessive bits before a new SOF shall be accepted	N <sub>Bits_idle</sub>	N <sub>bit(idle)</sub>	number of idle bits							
Bitfiter in CAN FD data phase	1	1	1							
CAN FD data phase bitfilter (option 1)	pBitfilter <sub>option1</sub>	t <sub>fltr(bit)dom</sub>	dominant bit filter time							
HS-PMA bus biasing control timings										
CAN activity filter time, long	t <sub>Filter</sub>	t <sub>wake(busdom)</sub> [1]	bus dominant wake-up time							
CAN activity filter time, short		t <sub>wake(busrec)</sub> [1]	bus recessive wake-up time							
Wake-up timeout, short	t <sub>Wake</sub>	t <sub>to(wake)bus</sub>	bus wake-up time-out time							
Wake-up timeout, long										
Timeout for bus inactivity	t <sub>Silence</sub>	t <sub>to(silence)</sub>	bus silence time-out time							
Bus Bias reaction time	t <sub>Bias</sub>	t <sub>d(busact-bias)</sub>	delay time from bus active to bias							

[1] t<sub>fitr(wake)bus</sub> - bus wake-up filter time, in devices with basic wake-up functionality

# **19. Revision history**

## Table 39. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
TJA1145A v.2	20200923	Product data sheet	-	TJA1145A v.1	
Modifications:	Added variants TJA1145AT and TJA1145AT/FD in an SO14 package.				
	<ul> <li><u>Table 31</u>: error corrected (CMC reset value changed to 01)</li> </ul>				
TJA1145A v.1	20190823	Product data sheet	-	-	

# 20. Legal information

## 20.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

# 20.2 Definitions

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